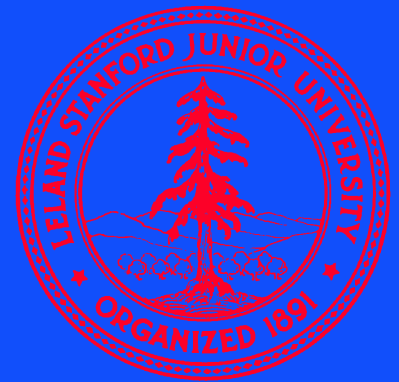
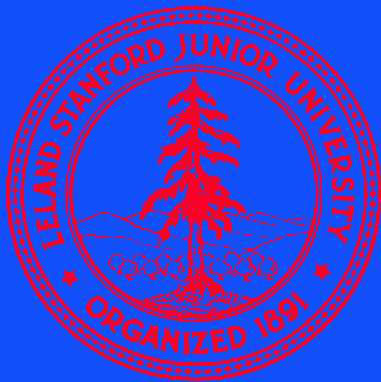
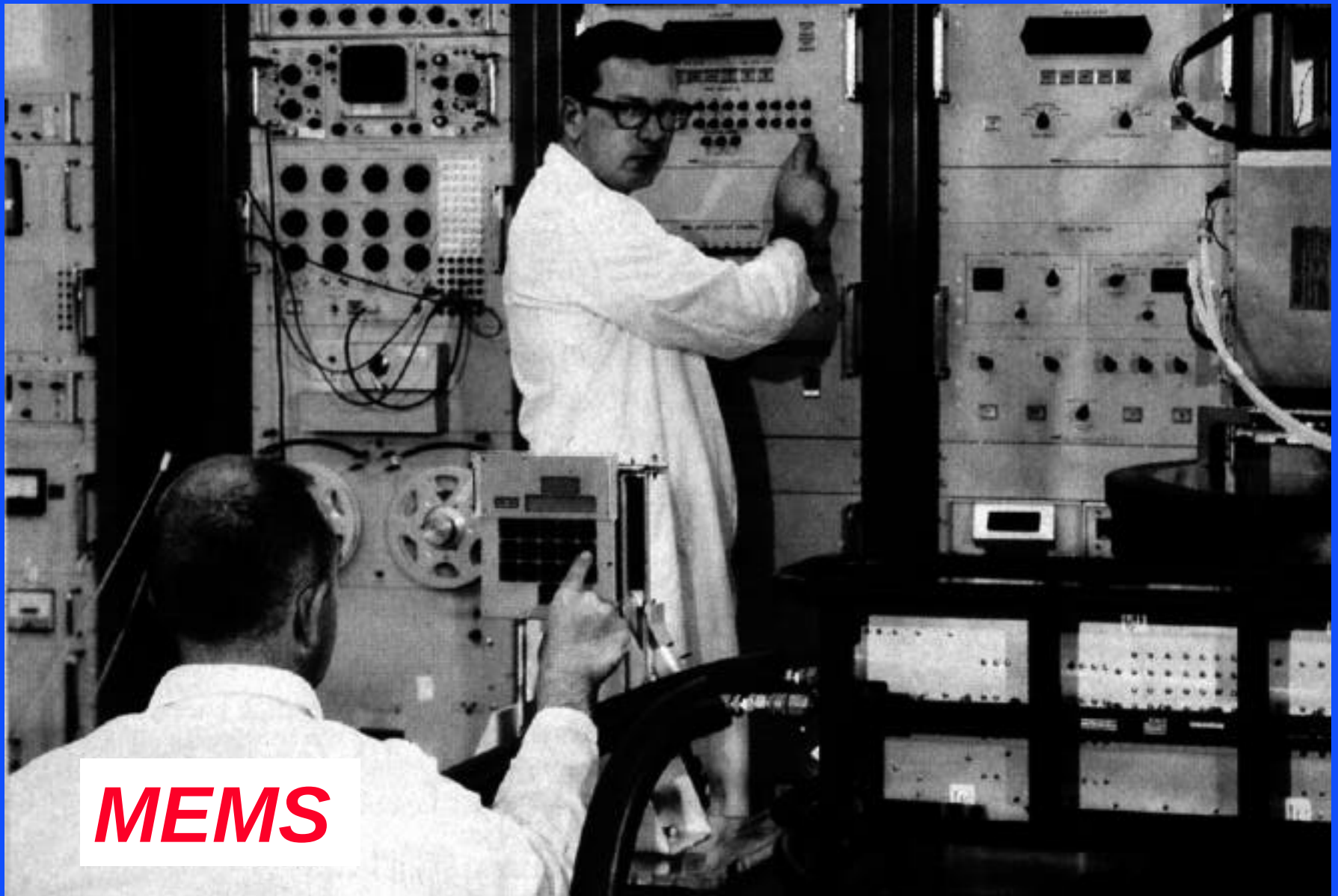


HISTORY OF MICROMACHINING

EE312, Prof. Greg Kovacs

Stanford University

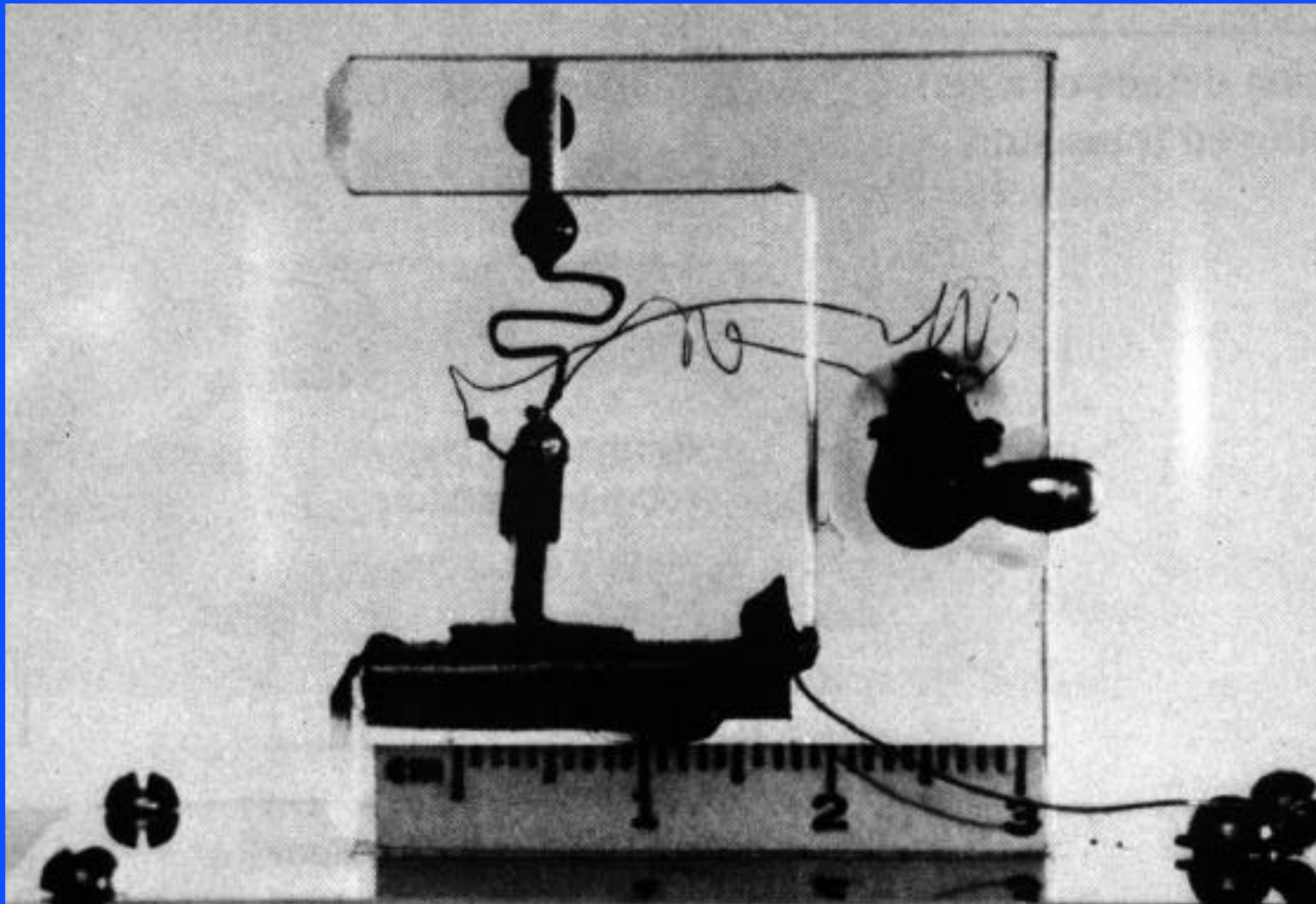




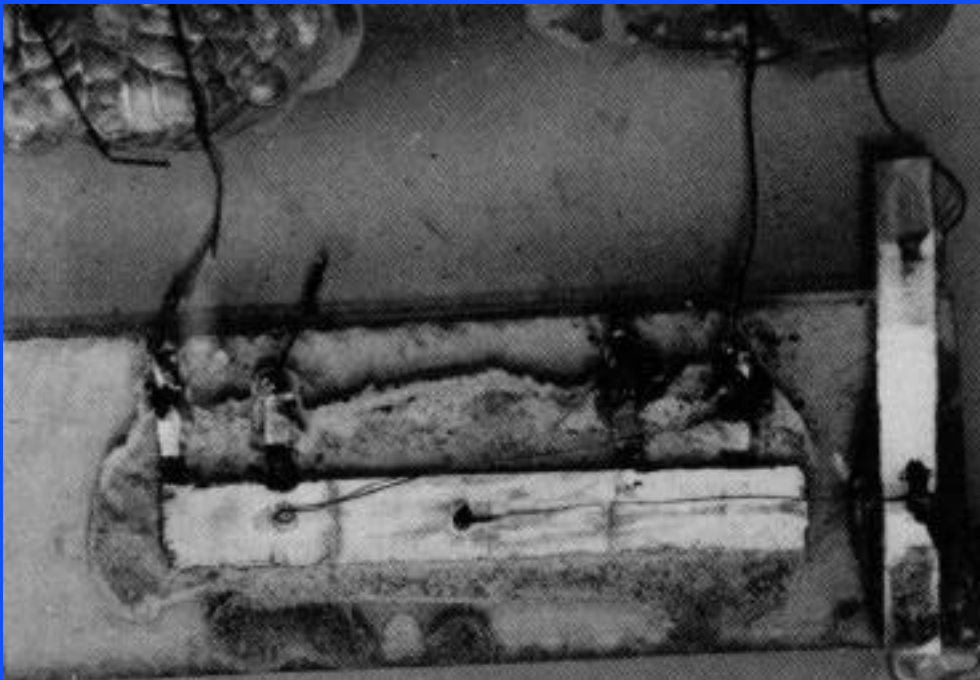
Original Image: TRW Archives.

G. Kovacs © 2002

First Transistor - Bell Labs c. 1947



First Integrated Circuits



First prototype integrated circuit, fabricated by Jack Kilby, summer 1958, Texas Instruments.

First advertisement for integrated circuits, Business Week, 3/26/60.

AVAILABLE NOW FROM TI

100:1 miniaturization with **SOLID CIRCUIT*** semiconductor networks

Now—3 years ahead of industry's expectations—
Solid Circuit semiconductor networks from Texas Instruments for many of your high-reliability miniaturized systems!

Solid Circuit networks are a major departure from conventional components because they integrate resistor, capacitor, diode, and transistor functions into a single high-purity semiconductor wafer. Protection and packaging of discrete elements is eliminated, and contacts between dissimilar materials are minimized, reducing element interconnections as much as 90%. Fabrication steps have been reduced to one-tenth those required for the same circuit function using conventional components.

Only a few process steps and time-proved TI mass production techniques permit a high degree of process control in **Solid Circuit** network fabrication. The result of these facts: reliability is built into each **Solid Circuit** network.

If you need to reduce equipment size and weight—or to design a more complex system in the same size—investigate **Solid Circuit** networks for your missile, satellite, space vehicle, and other microelectronic programs. TI engineers are ready to custom design this concept to your requirements. Contact your nearest TI Sales Engineer today. The TI Type 922 **Solid Circuit** network is immediately available for your evaluation.

SEMICONDUCTOR NETWORK CONCEPT

The concept of a semiconductor network is the relation of conductance paths in a semiconductor to the classical circuit elements, establishing an orderly design approach based on circuit knowledge. In this manner, semiconductor networks may be designed to perform the functions of a wide variety of existing circuits. Through the proper selection and shaping of semiconductor conductance paths, it is possible to realize such electronic functions as amplification, pulse formation, switching, attenuation, and oscillation.

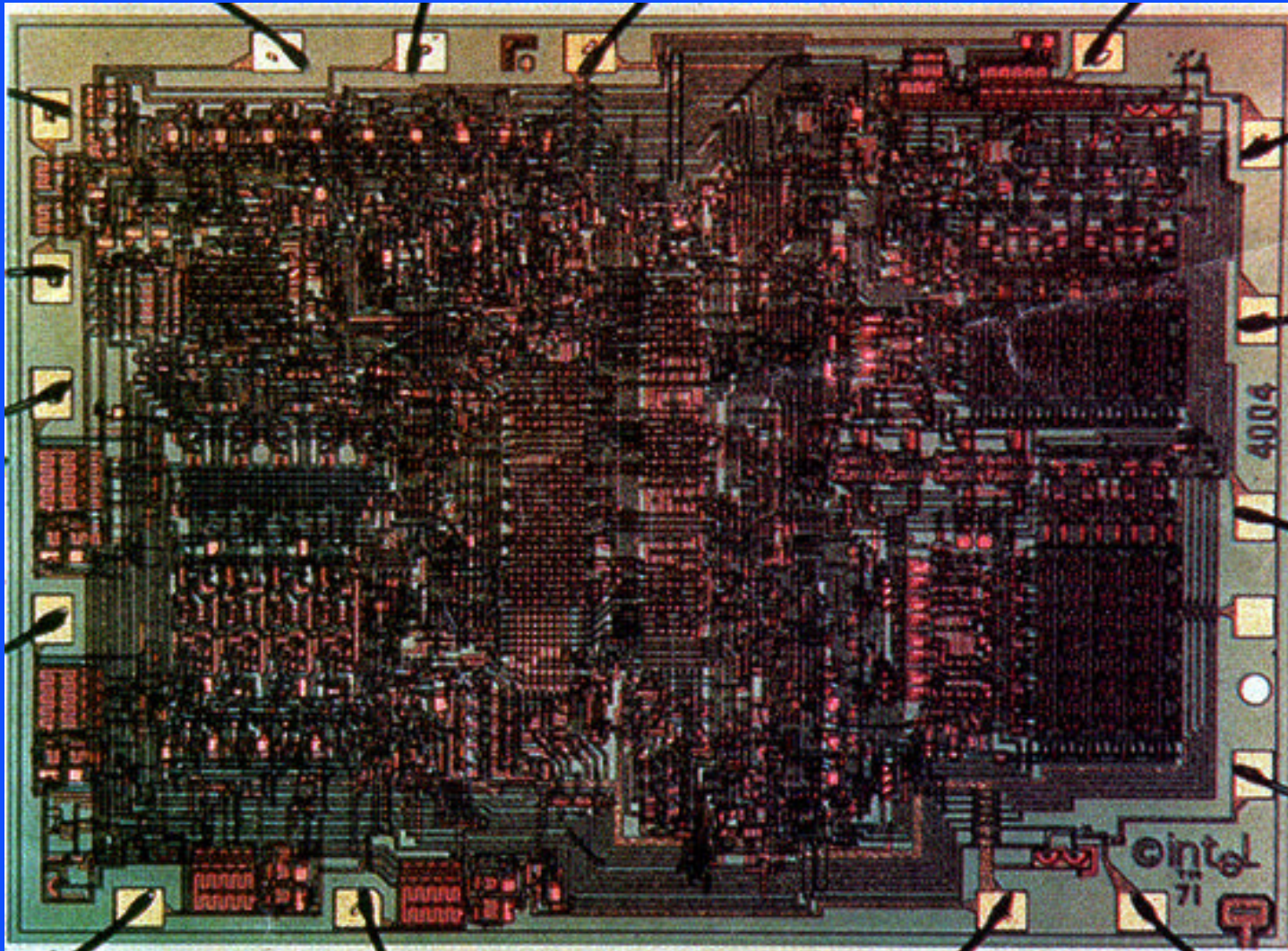
An assembly of 13 **Solid Circuit** networks, actual size, performs a full serial adder function, replacing 10 conventional components with a 100:1 size reduction. Weight: 1.5 gm. Volume: 0.01 cubic inch.

*Trademark of TEXAS INSTRUMENTS INCORPORATED

Diagram illustrating the semiconductor network concept, showing a central block (TI) with multiple input and output lines, labeled OUTPUT 2, OUTPUT 1, BASE 2, and BASE 1. Dimensions are provided for the network structure.

TEXAS INSTRUMENTS INCORPORATED
SEMICONDUCTOR COMPONENTS DIVISION
POST OFFICE BOX 212 - DALLAS, TEXAS

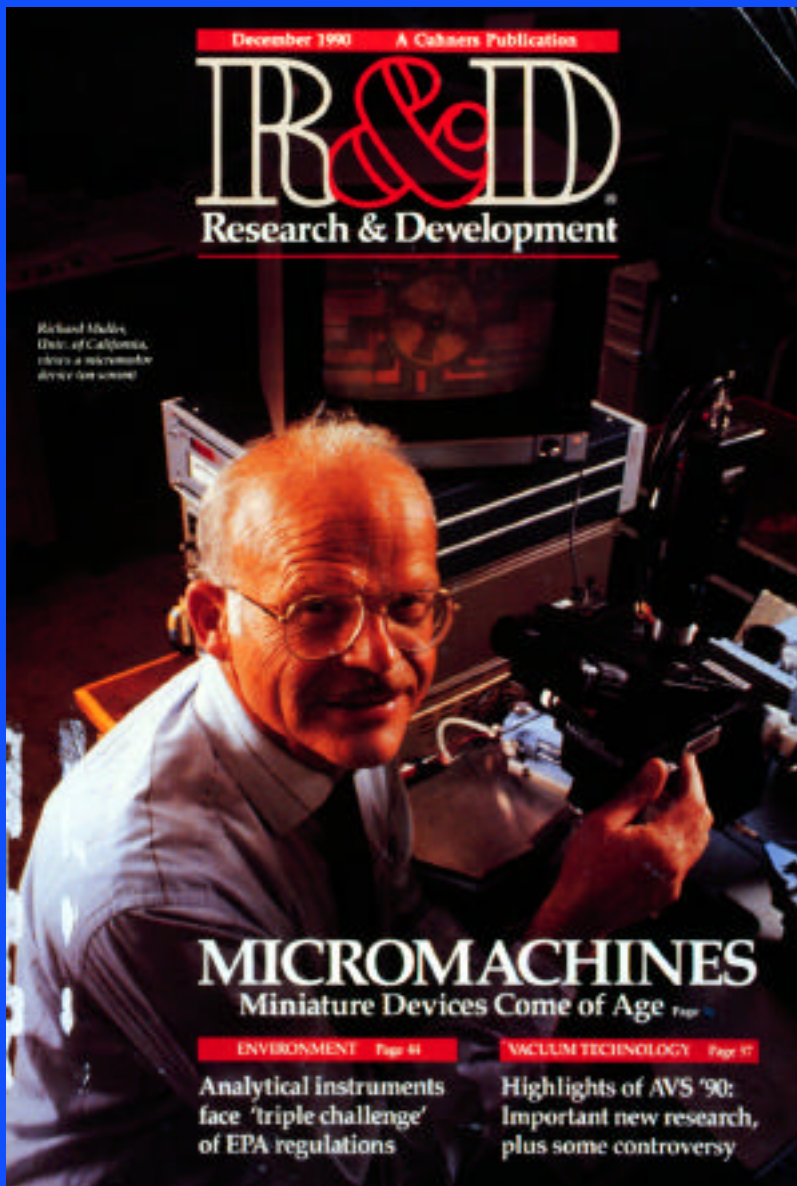
First Microprocessor - Intel 4004 - 1971



Micromachined sensors and actuators, or “MEMS” were made possible by the existence of cleanrooms for making conventional integrated circuits.



What's In a Name?



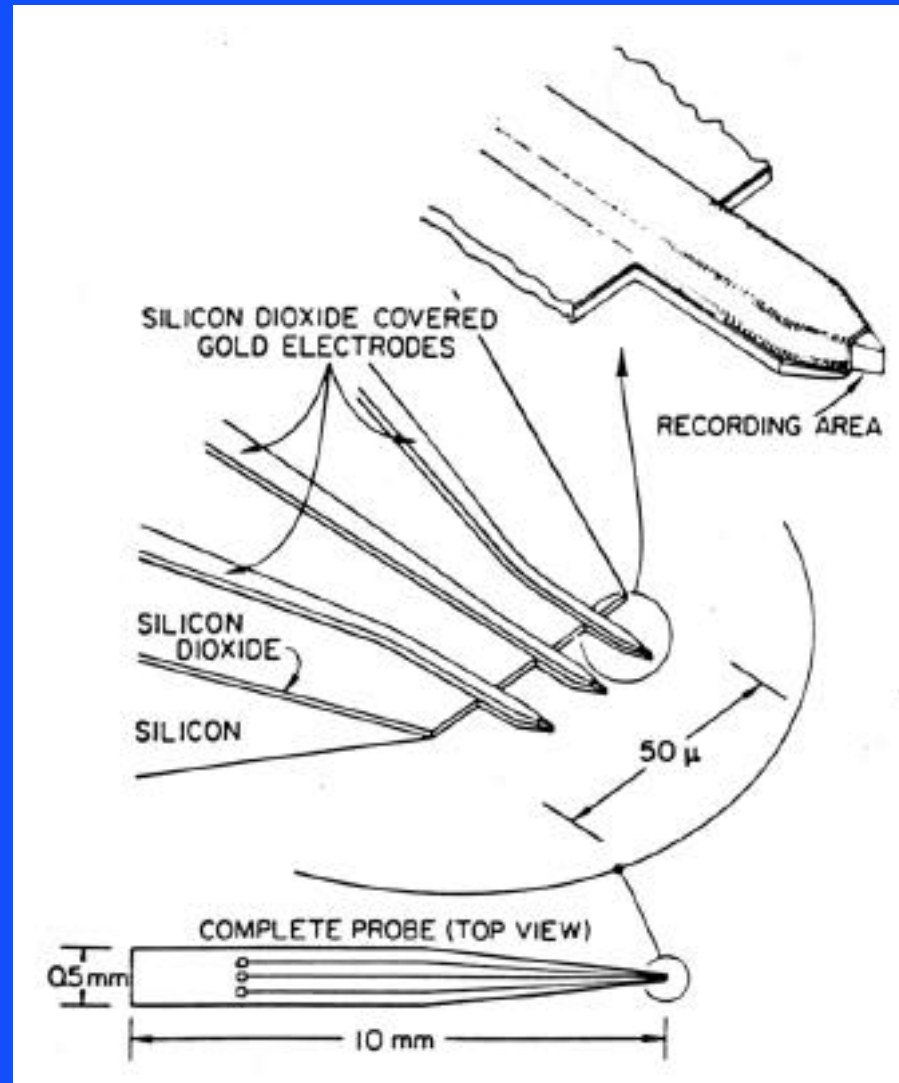
Micromachined devices are certainly not new. In fact, the origins of some of the major “families” of devices can be traced back to the 1960’s and 1970’s.

Early MEMS Work at Stanford

- Early “MEMS” work funded by NASA and NIH - before NSF and DARPA came on the scene.
- Wise - Brain Probes - c. 1966.
- Samaun - Relative Pressure Sensor - c. 1969.
- Nunn - Micro Strain Gauge - c. 1972.
- Terry - Gas Chromatography System - c. 1972.
- Roylance - Micromachined Accelerometer - c. 1974.
- Barth - Absolute Pressure Sensor - c. 1974.

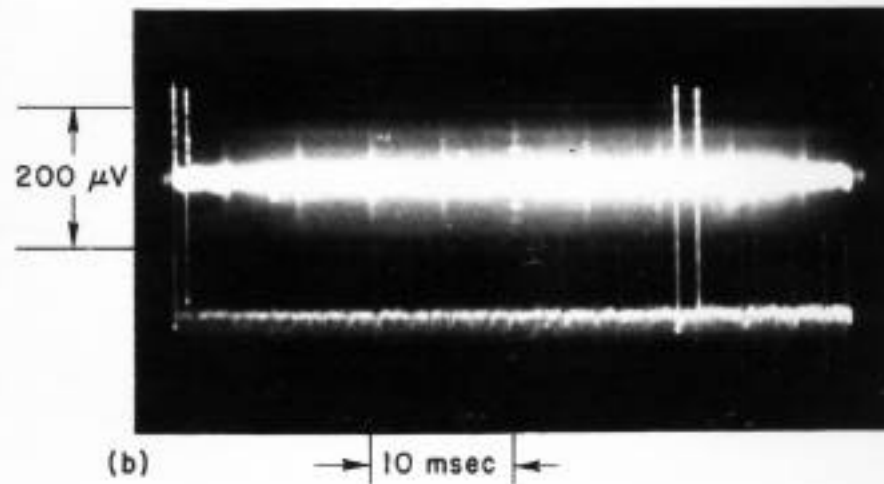
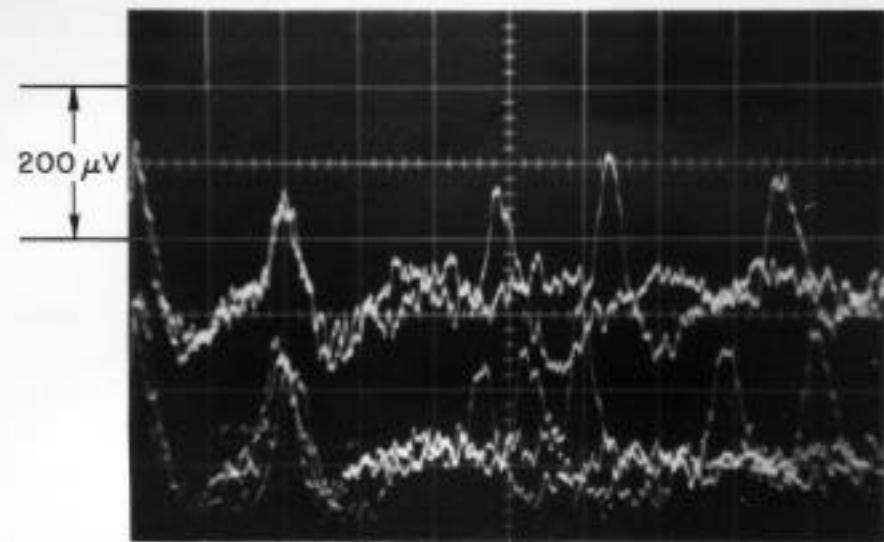
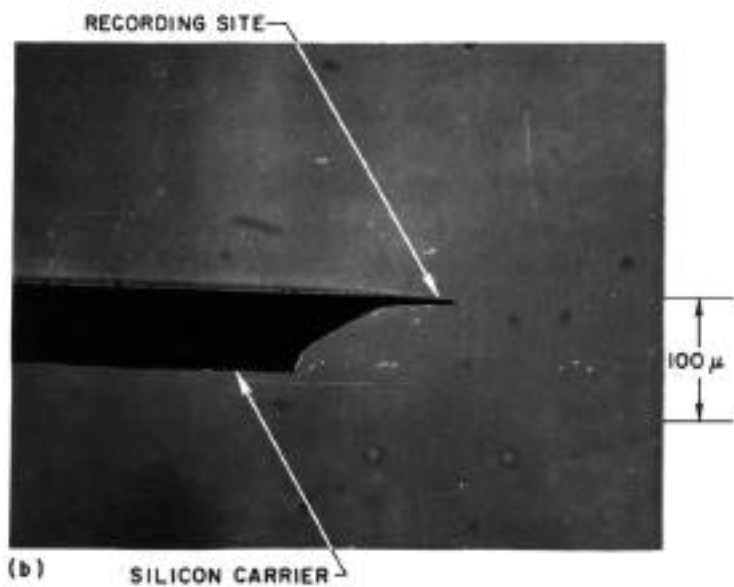
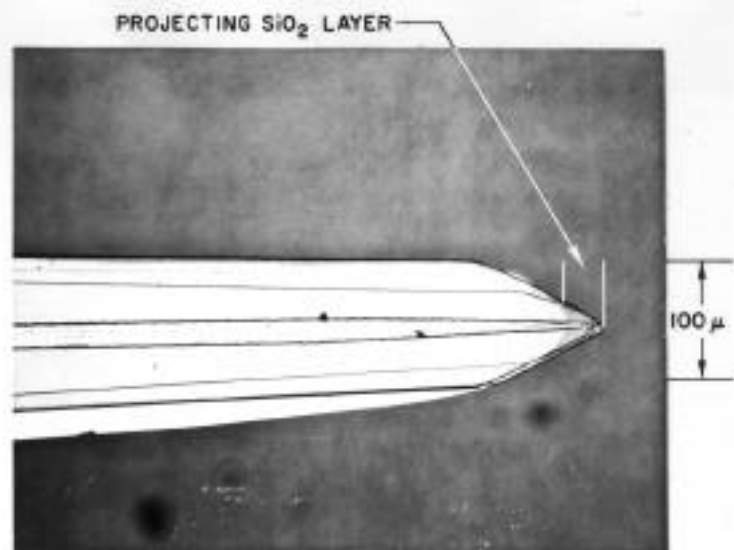
(Thanks to Prof. Jim Angell for his archives and recollections.)

Ken Wise Brain Probe - 1966



Courtesy Prof. Ken Wise, U. Michigan.

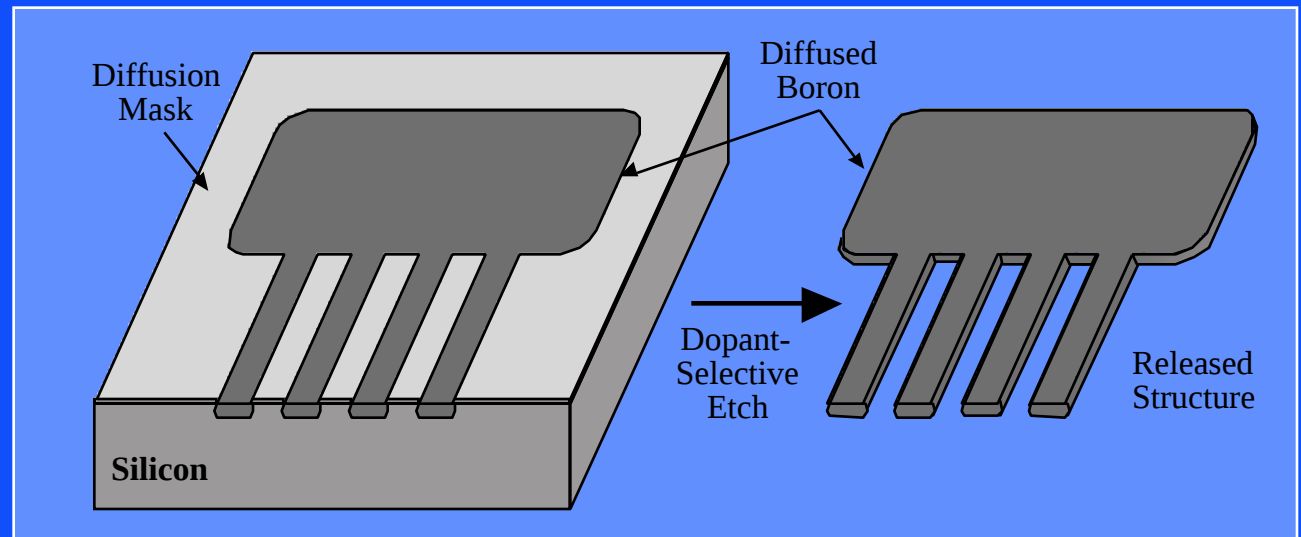
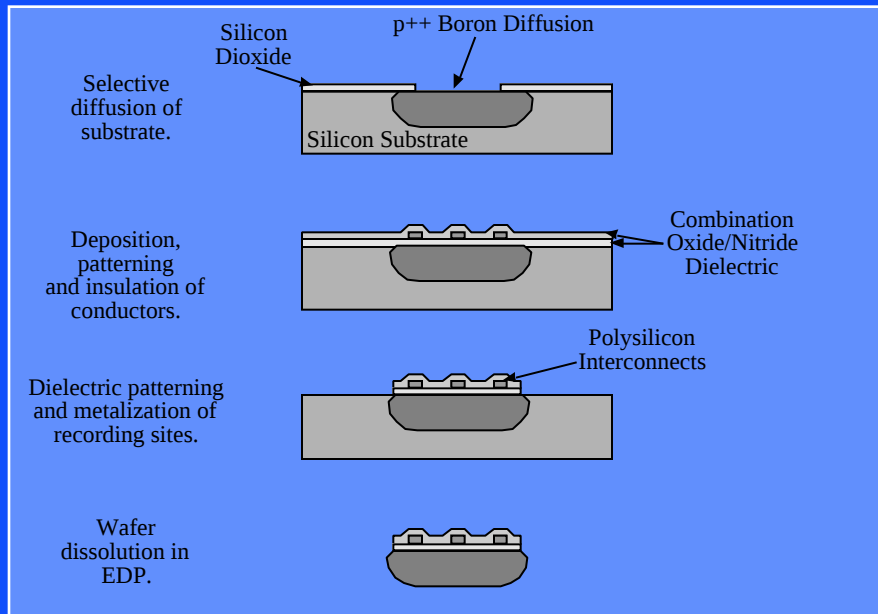
G. Kovacs © 2002

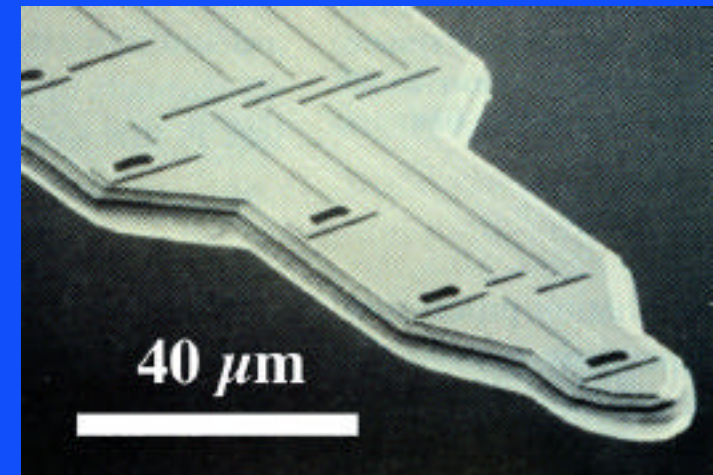
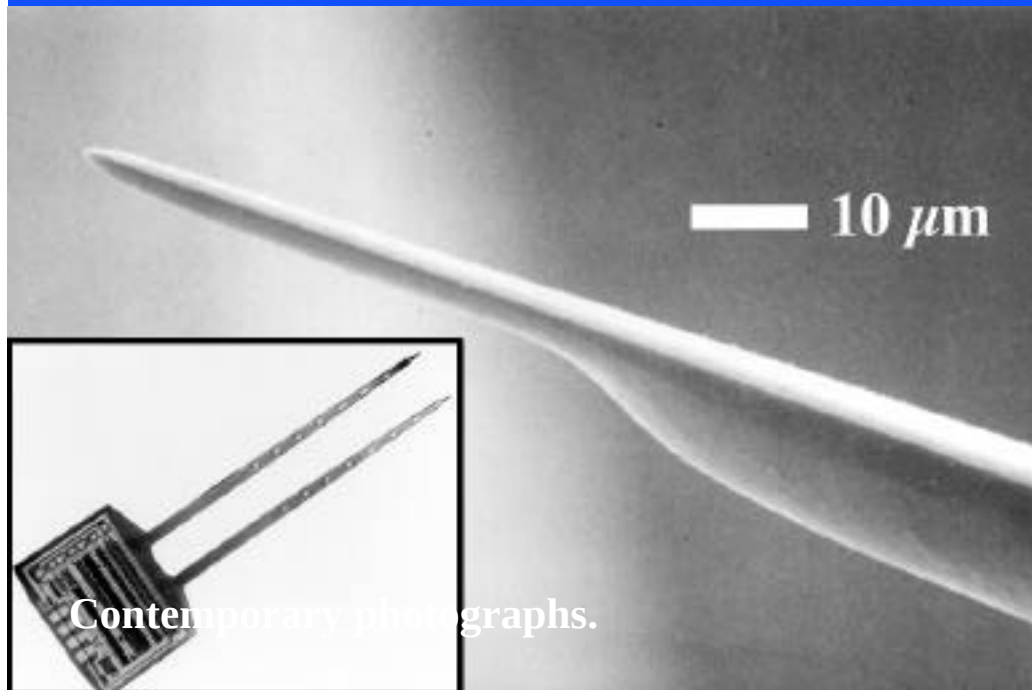
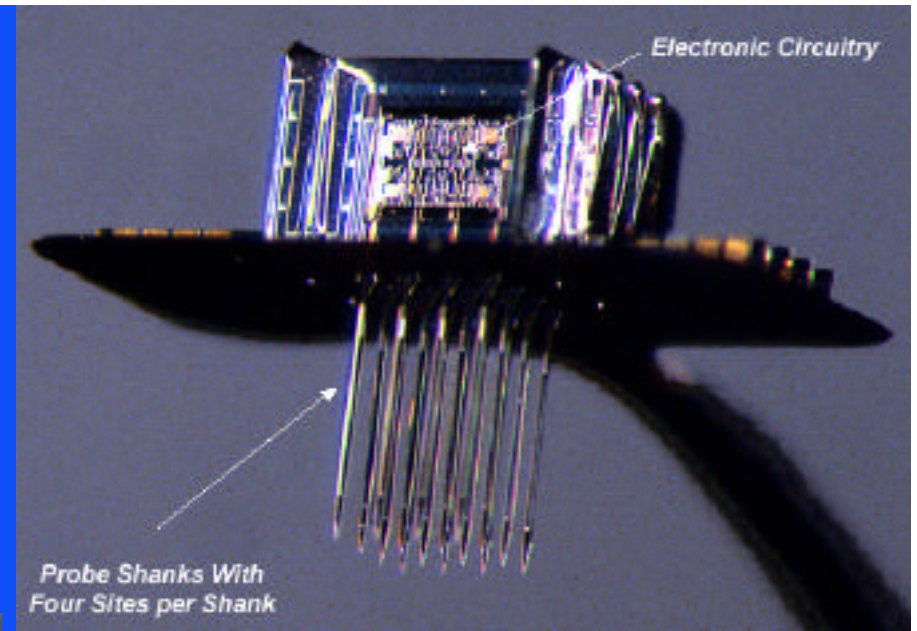
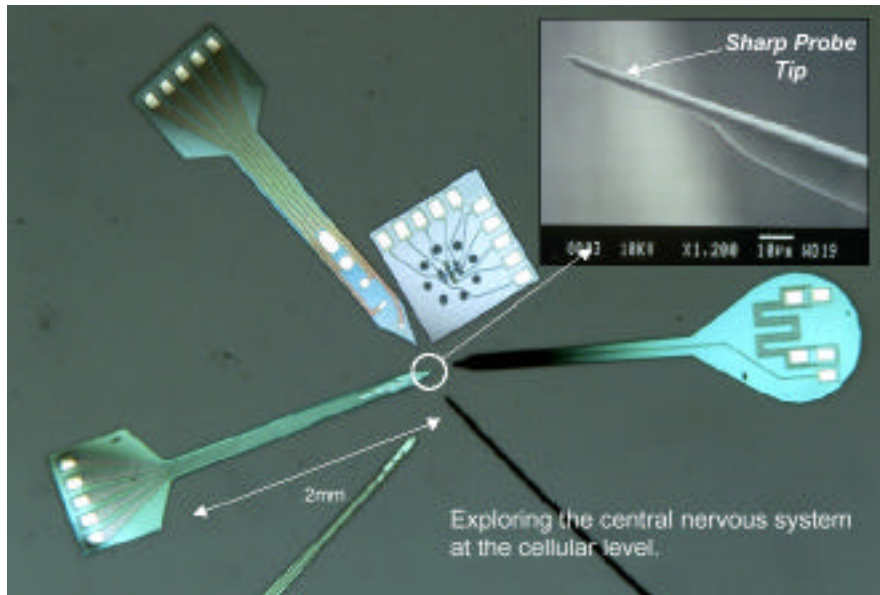


Courtesy Prof. Ken Wise, U. Michigan.

G. Kovacs © 2002

Ken Wise Brain Probe - 1966





Courtesy Prof. Ken Wise, U. Michigan.

Samaun Relative Pressure Sensor - 1969

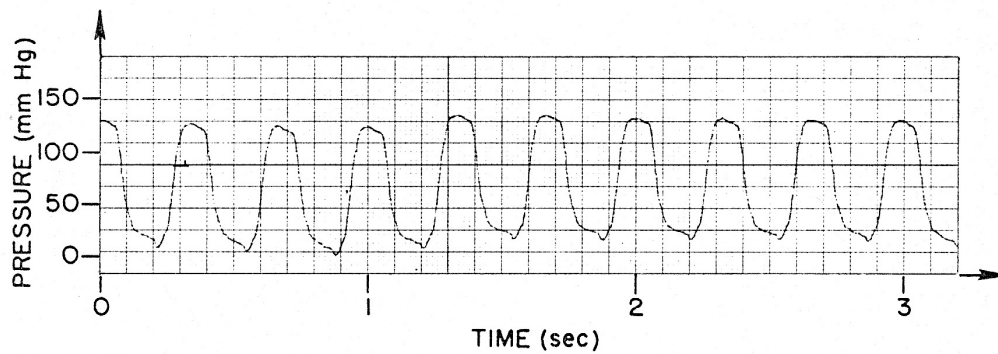
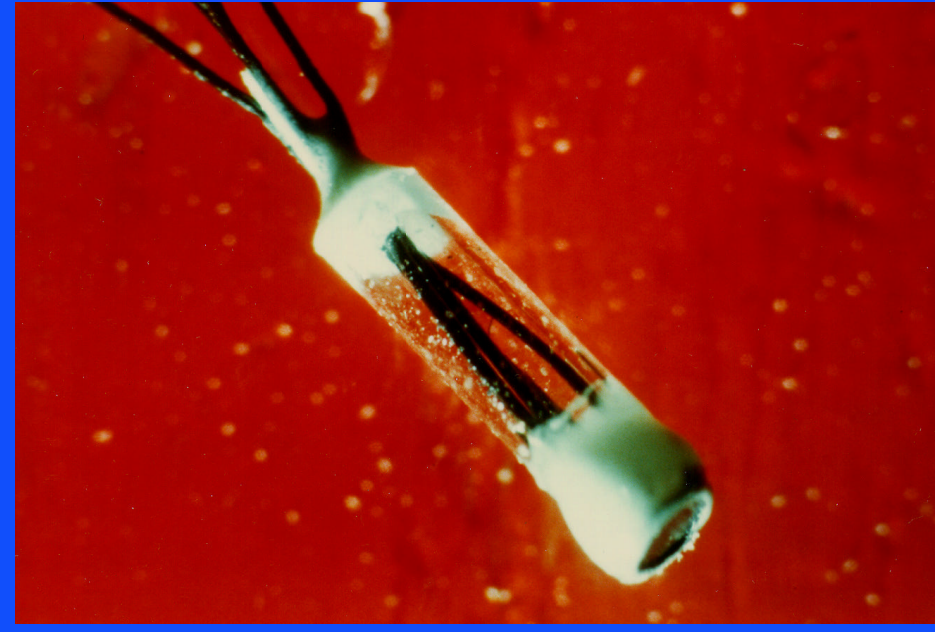
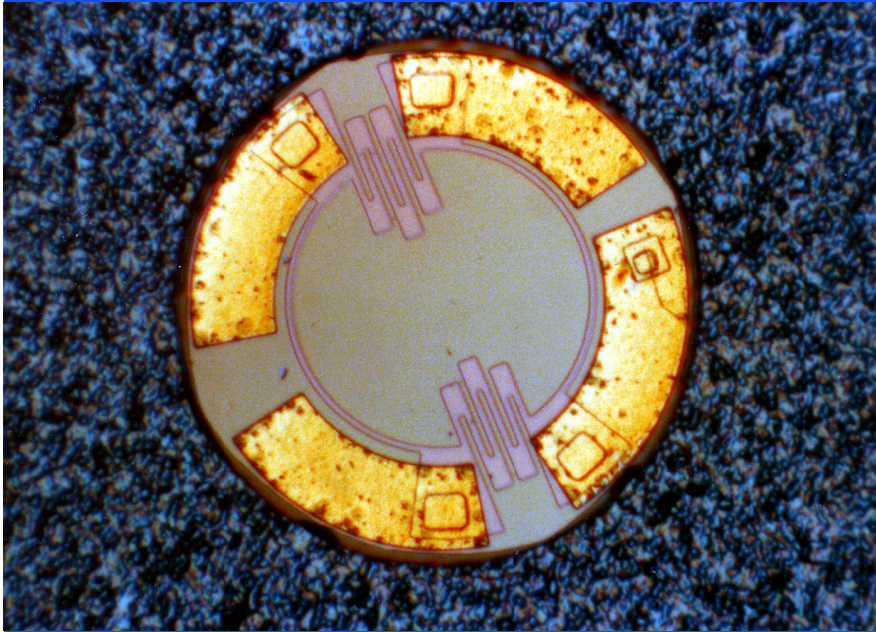
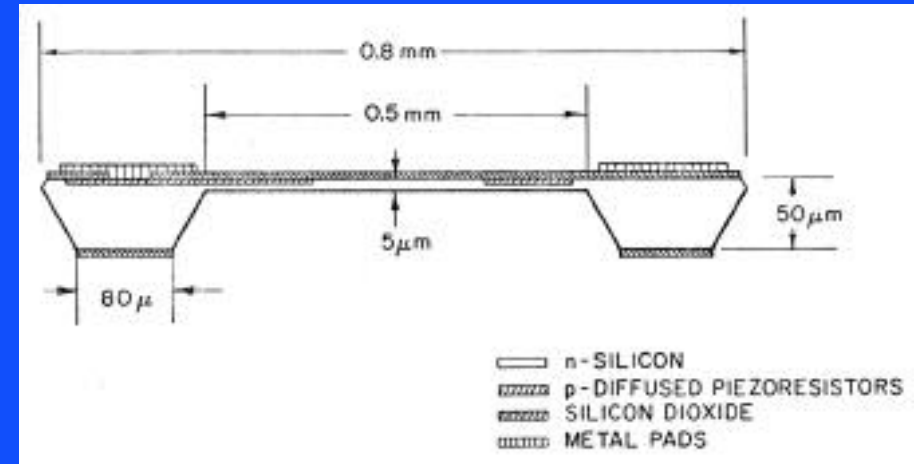


Fig. 5.2. Recording of the blood pressure in the left ventricle of a dog.

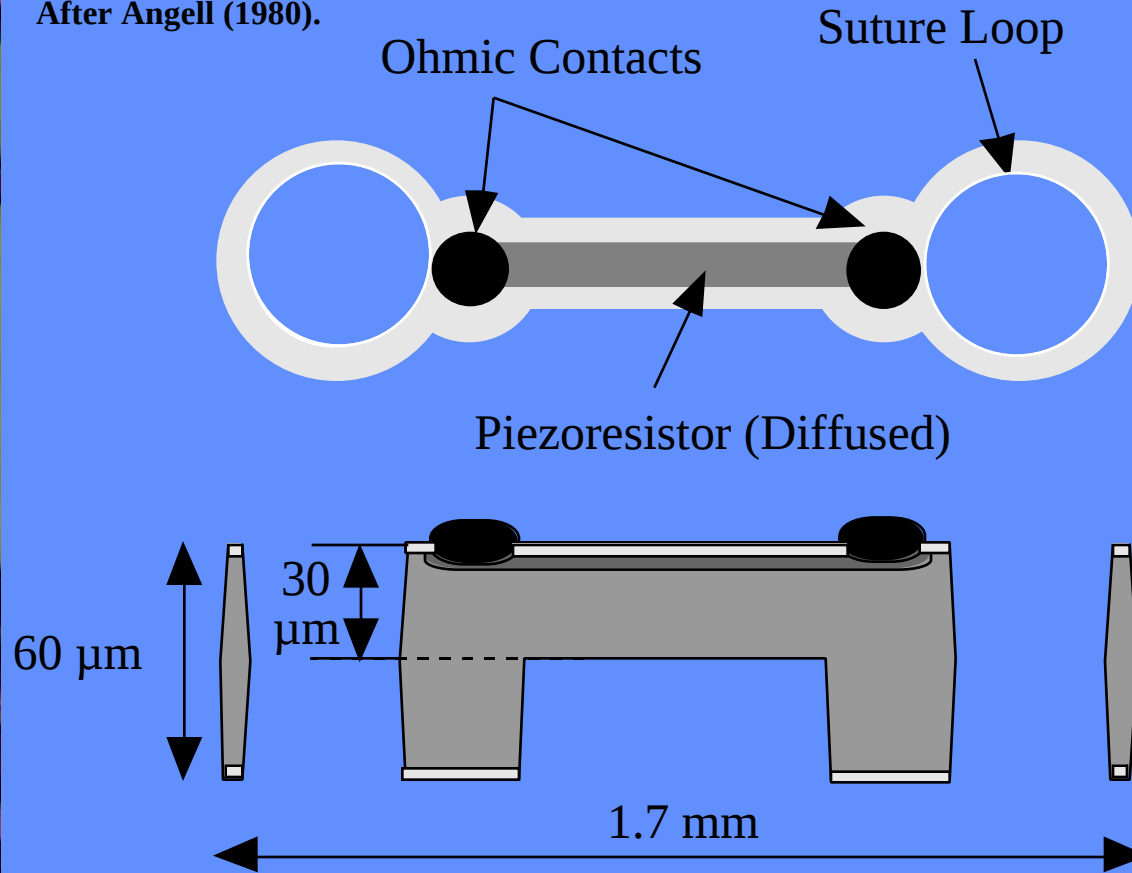




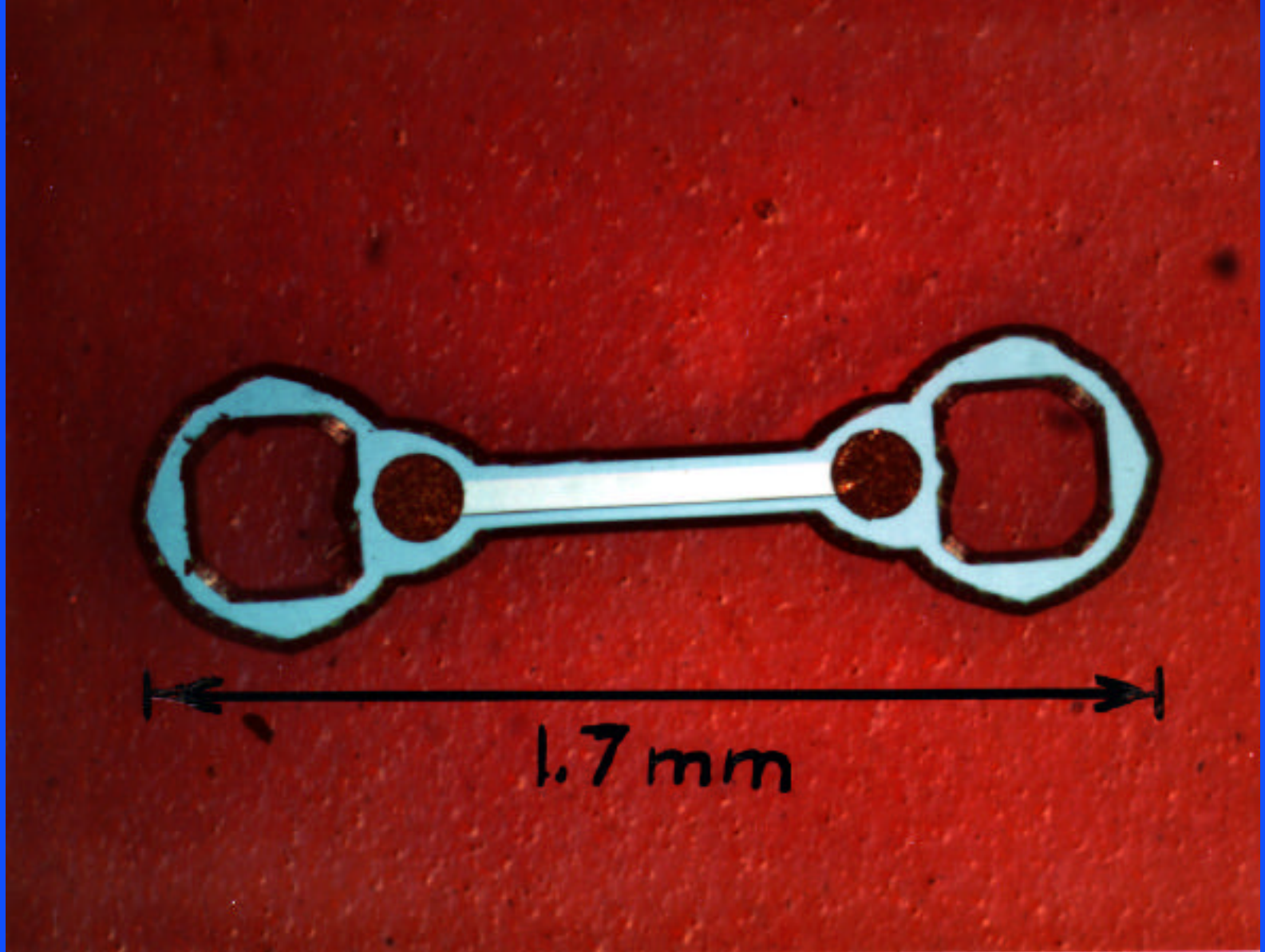
Nunn - Micro Strain Gauge - 1972



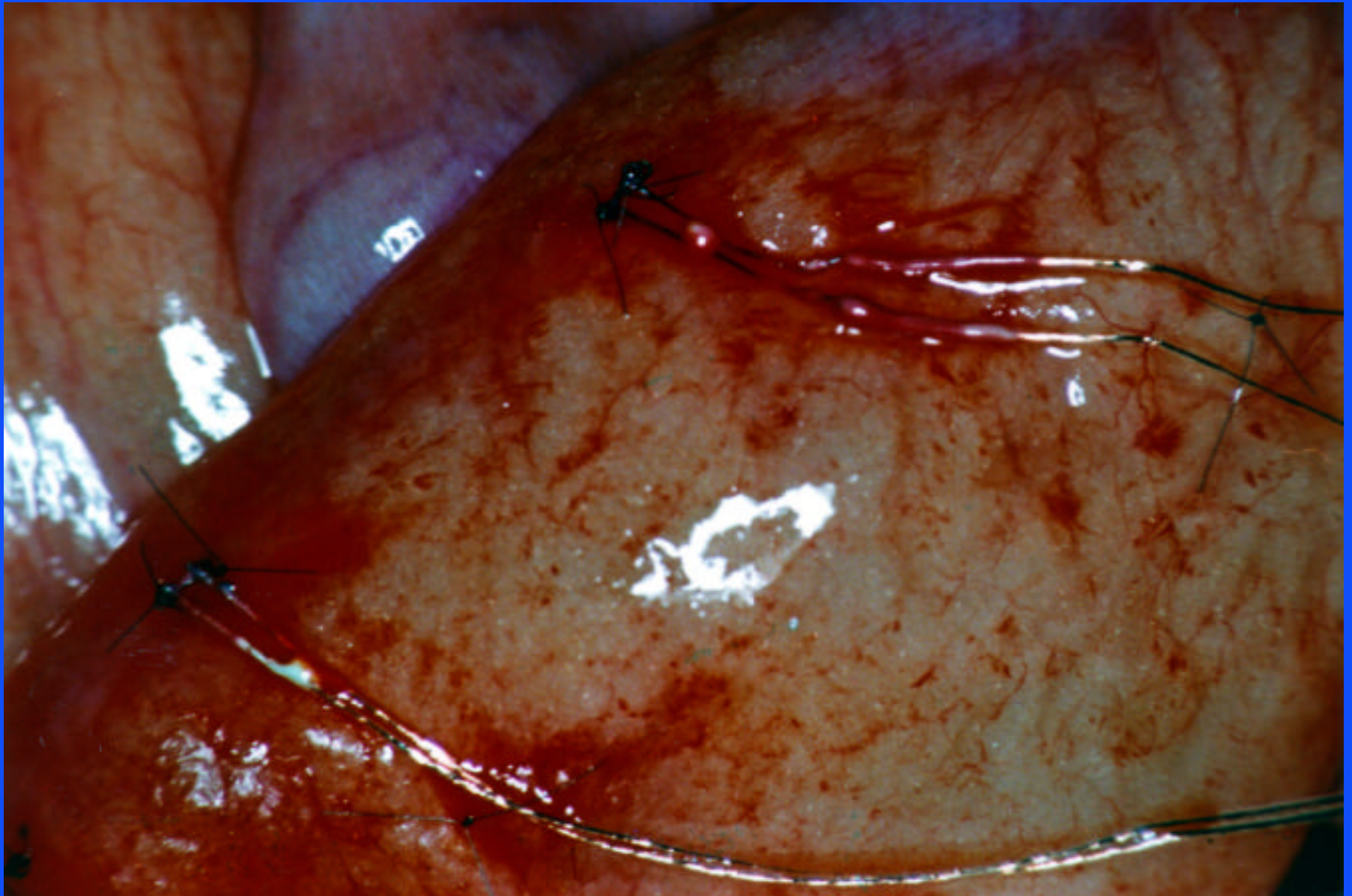
After Angell (1980).

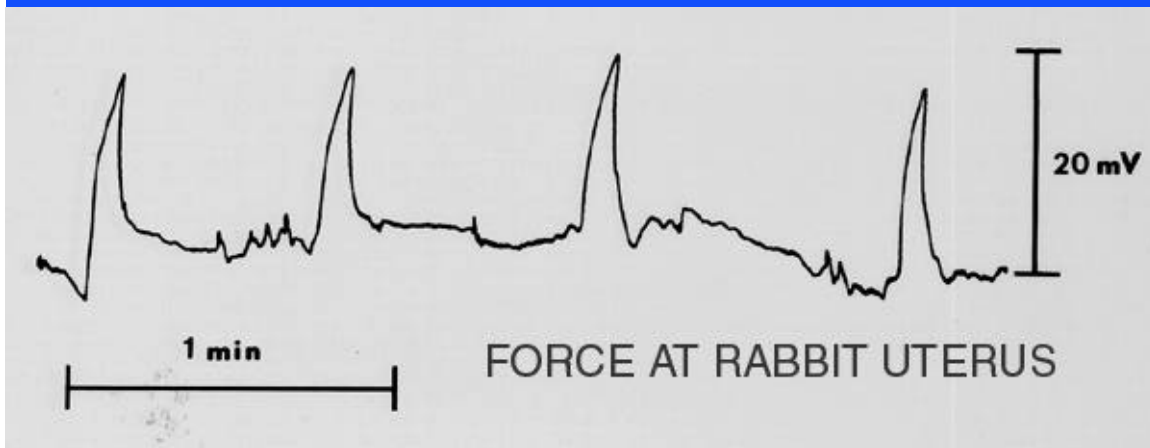
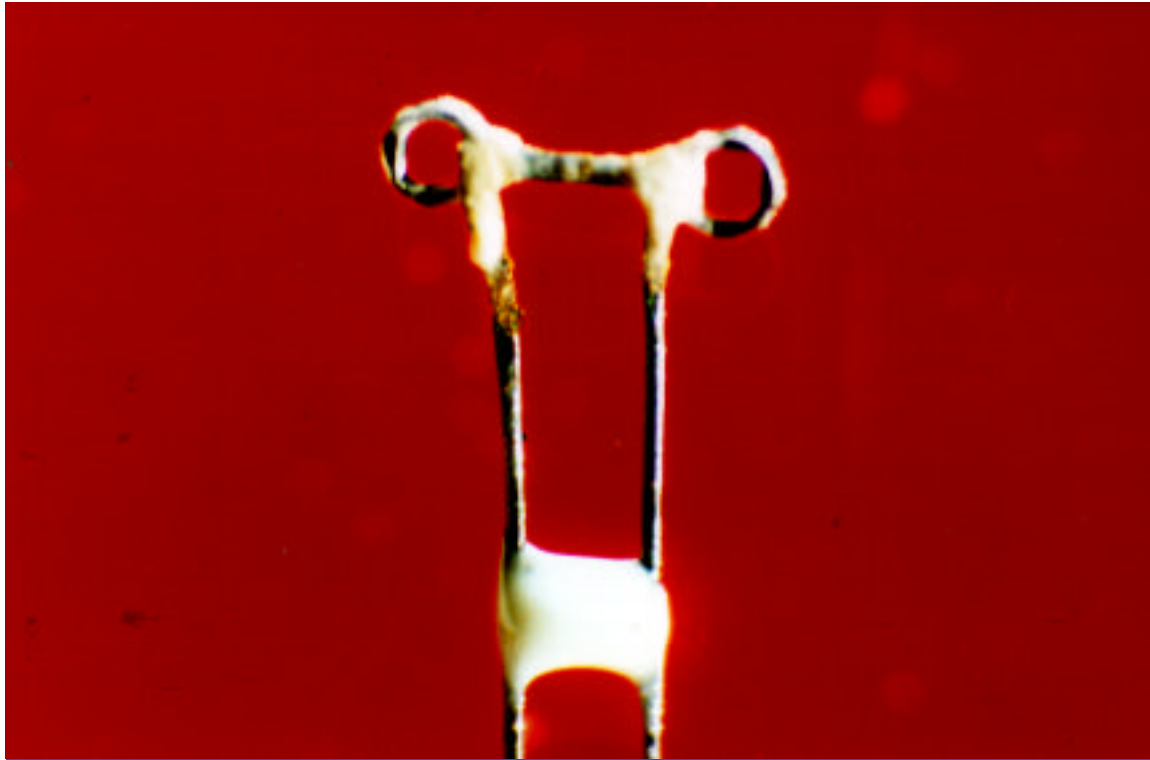


Reference: Angell, J. B., "Transducers for in vivo measurement of force, strain and motion," in "Physical Sensors for Biomedical Applications," Neuman, M. R., Fleming, D. G., Cheung, P. W., and Ko, W. H. [eds.], CRC Press, Boca Raton, FL, 1980, pp. 46 - 53.

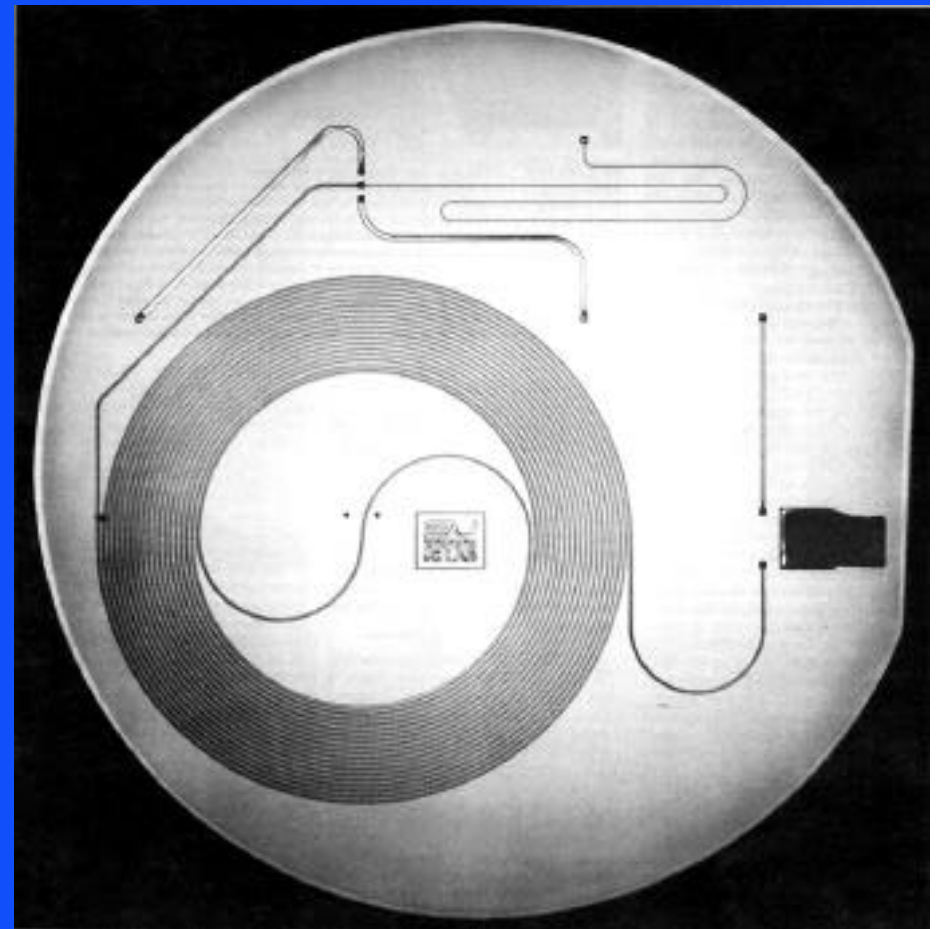
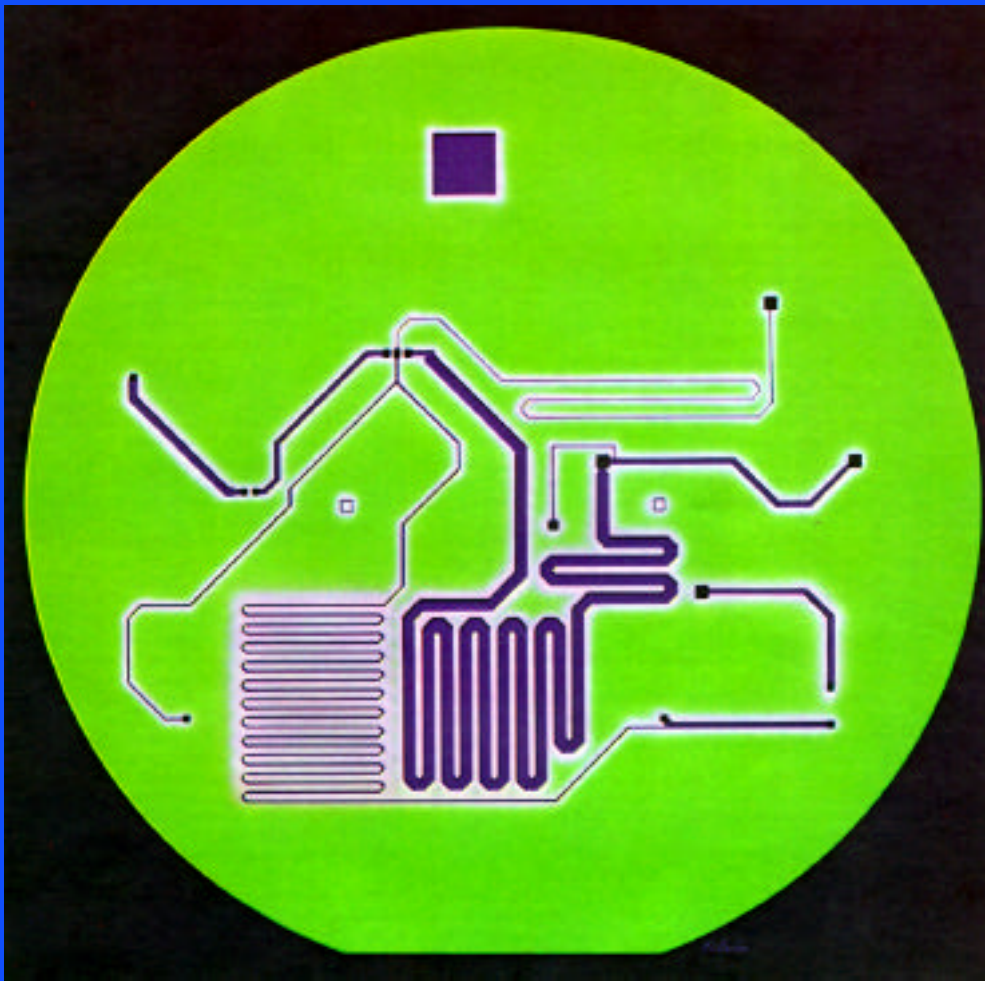




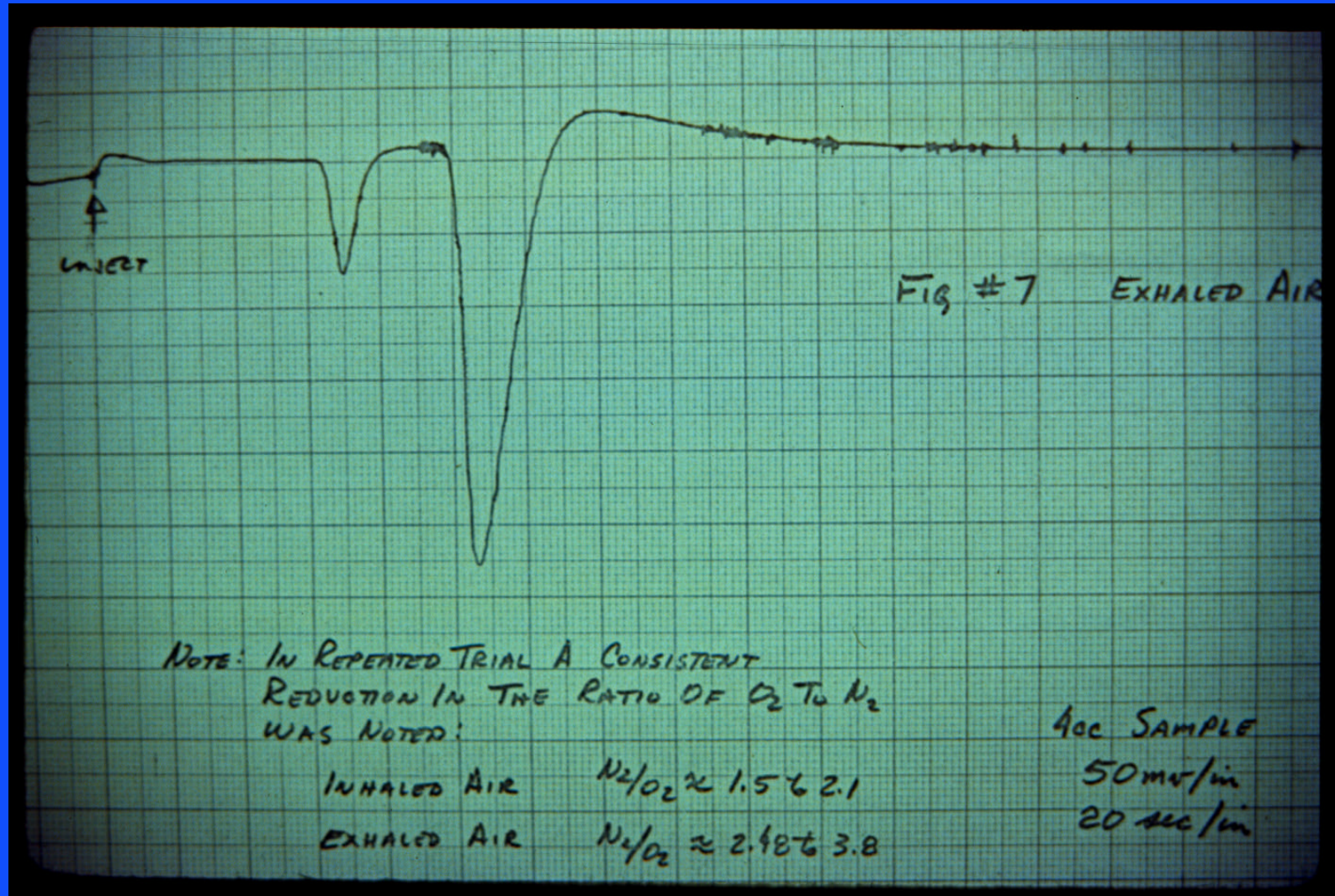




Terry - Integrated Gas Chromatography System - 1972

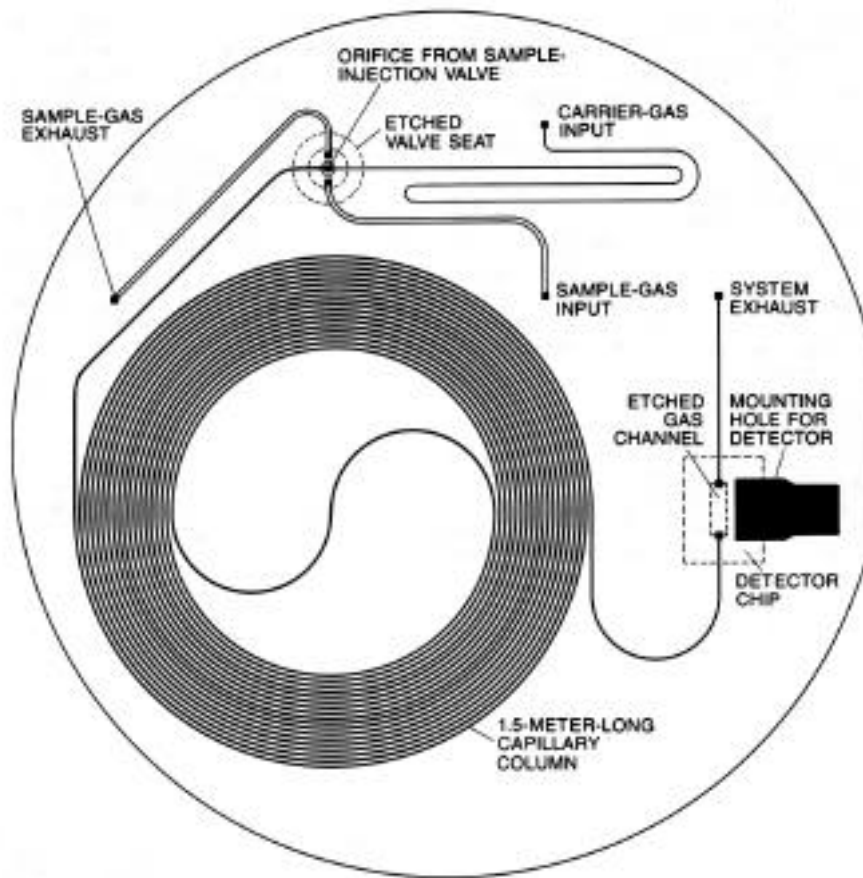


GC Data - 1972



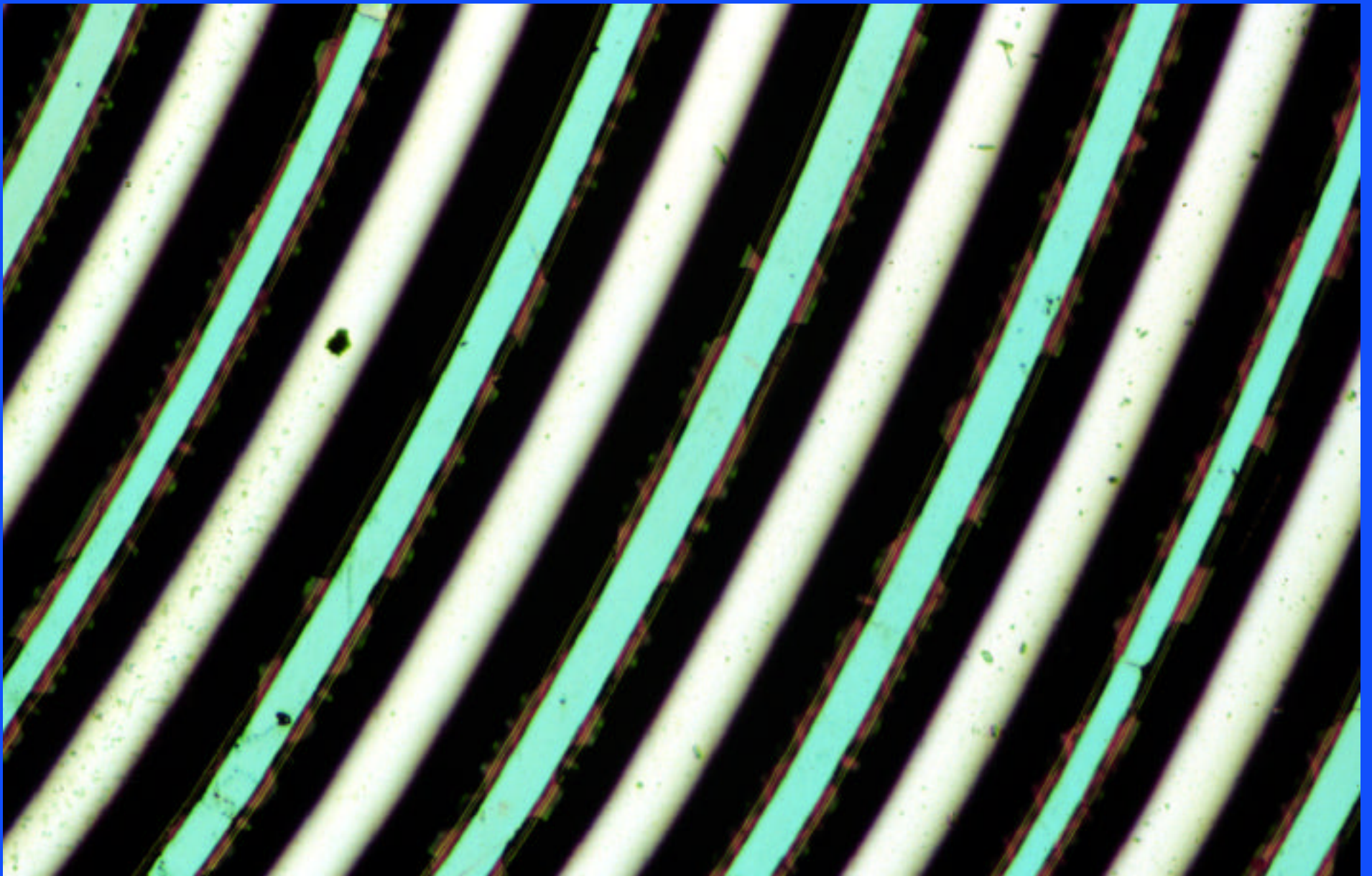
Courtesy Dr. Steve Terry, EG&G IC Sensors.

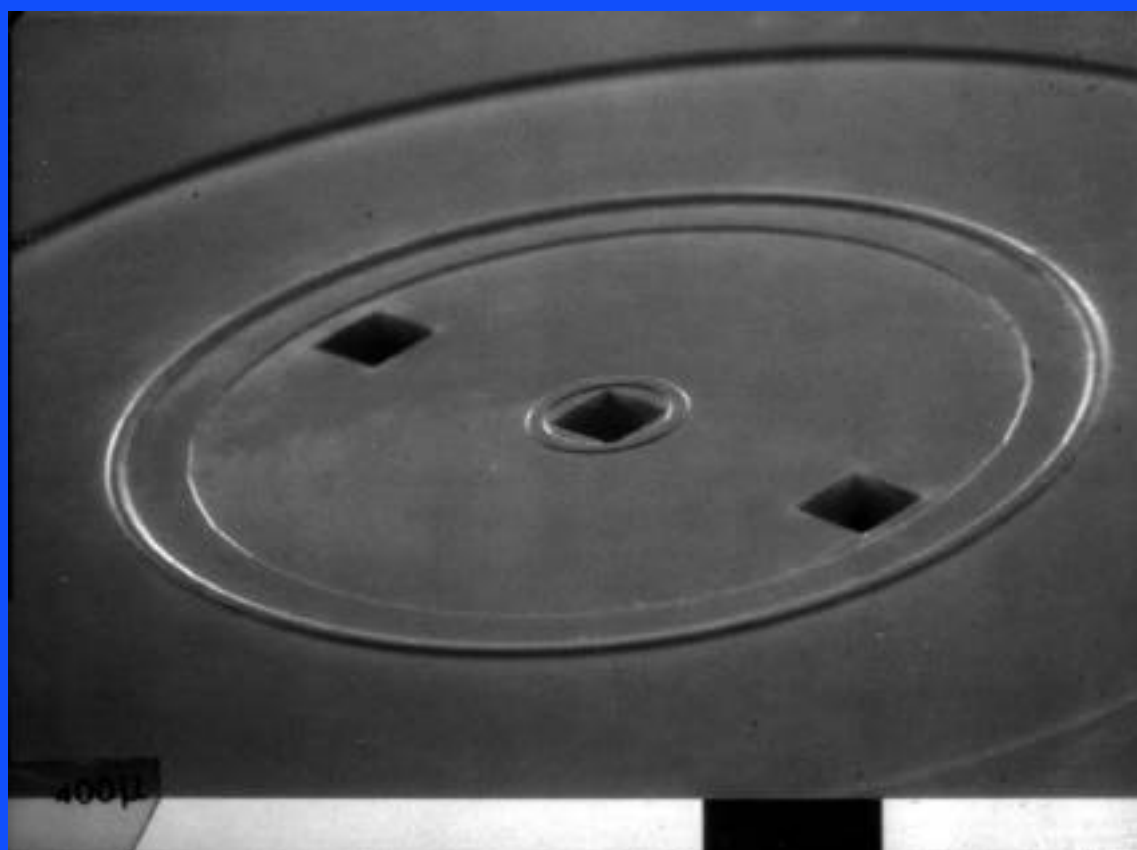
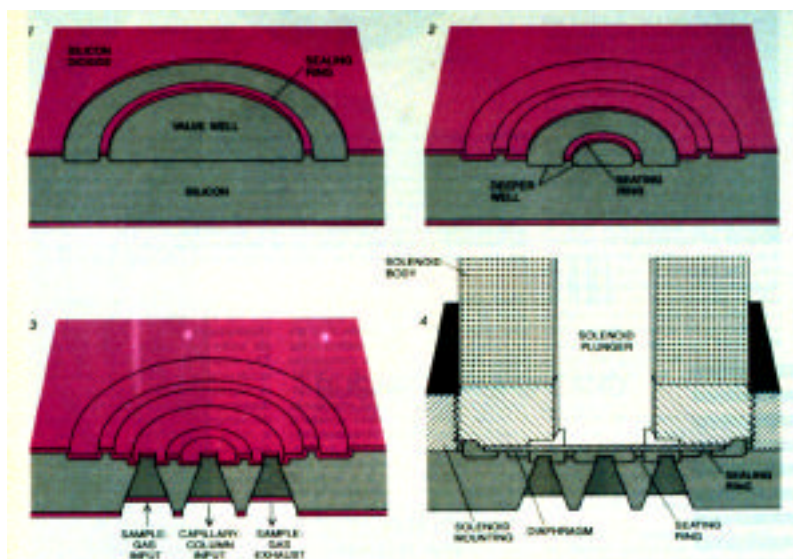
GAS CHROMATOGRAPHY SYSTEM



Source: Terry, S. C., Jerman, J. H., and Angell, J. B., "A Gas Chromatographic Air Analyzer Fabricated on a Silicon Wafer," IEEE Transactions on Electron Devices, vol. ED-26, no. 12, Dec. 1979, pp. 1880 - 1886.

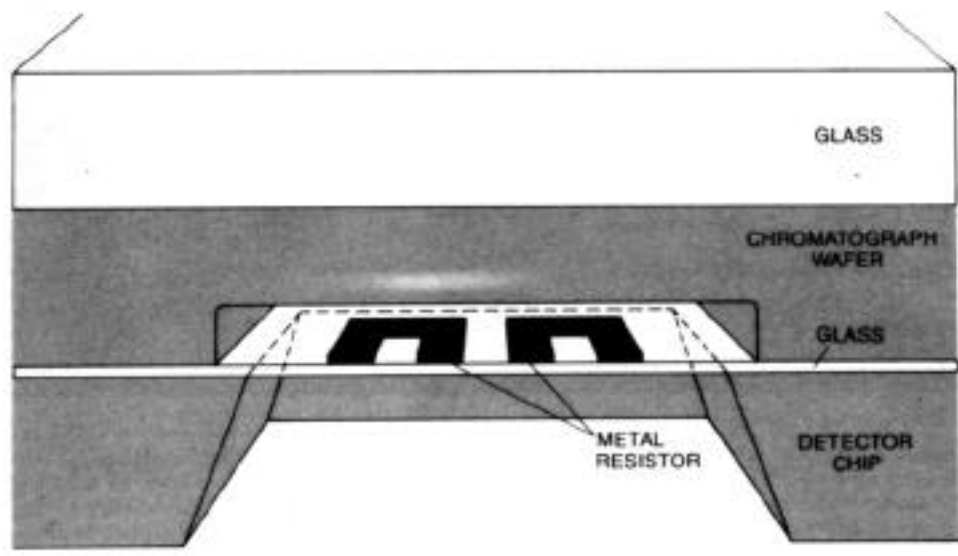
Courtesy Dr. S. Terry, EG&G IC Sensors, Inc.
1.5 meter GC column on 2" wafer.





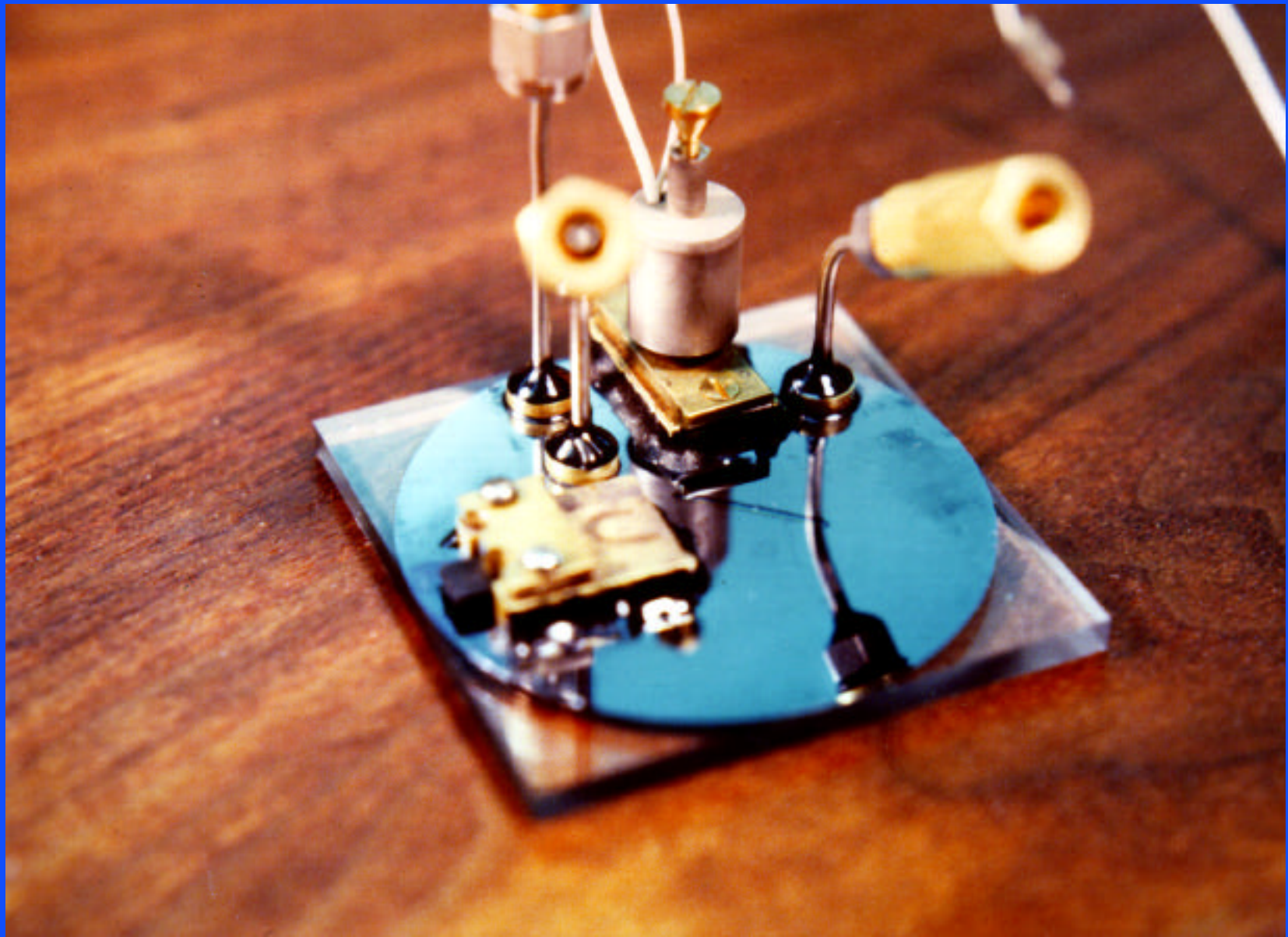
Courtesy Dr. S. Terry, EG&G IC Sensors, Inc.

G. Kovacs © 2002



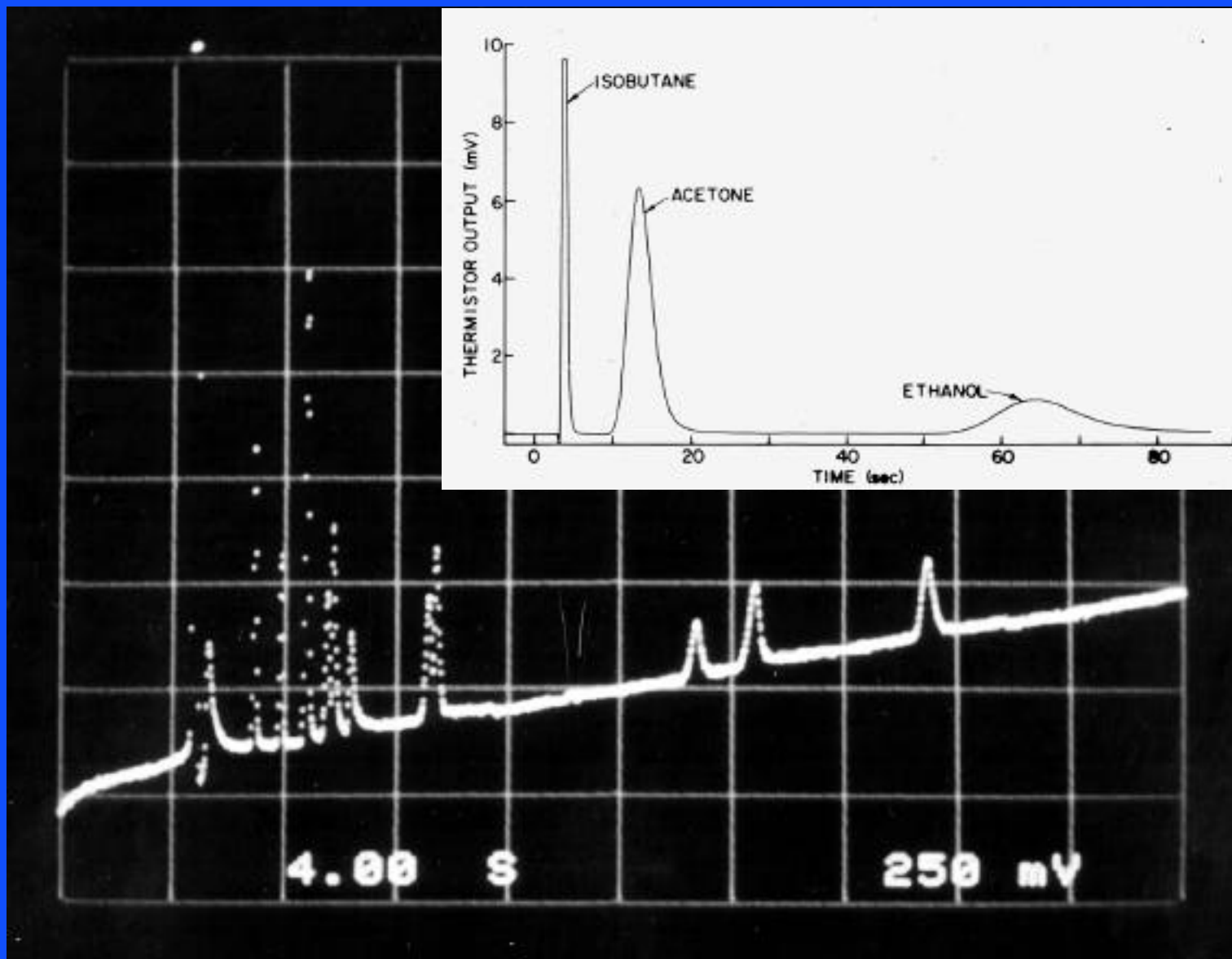
Courtesy Dr. S. Terry, EG&G IC Sensors, Inc.

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Courtesy Dr. S. Terry, EG&G IC Sensors, Inc.

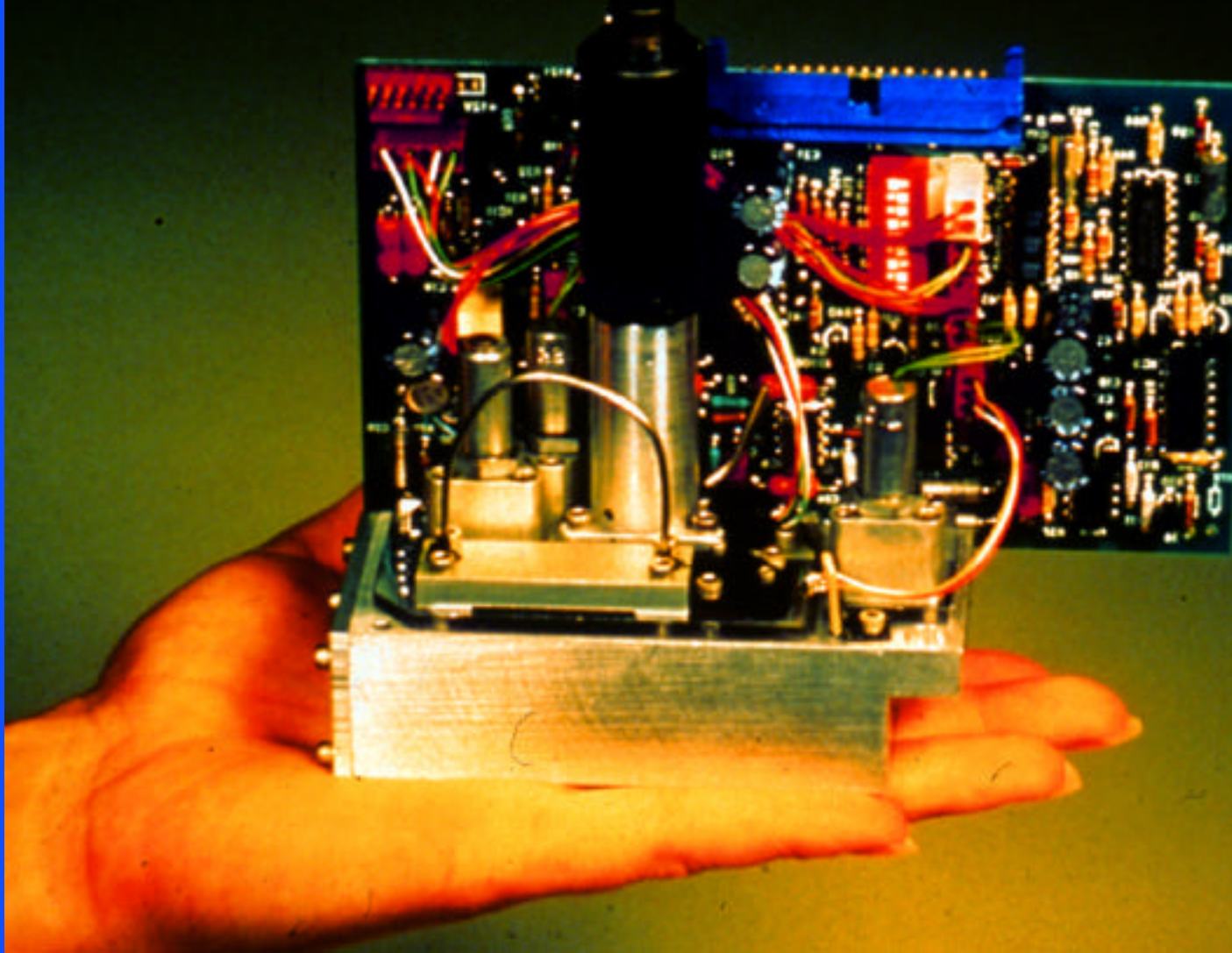
G. Kovacs © 2002



Courtesy Dr. S. Terry, EG&G IC Sensors, Inc.

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Commercialization Effort



Courtesy Prof. K. Petersen, Stanford University.

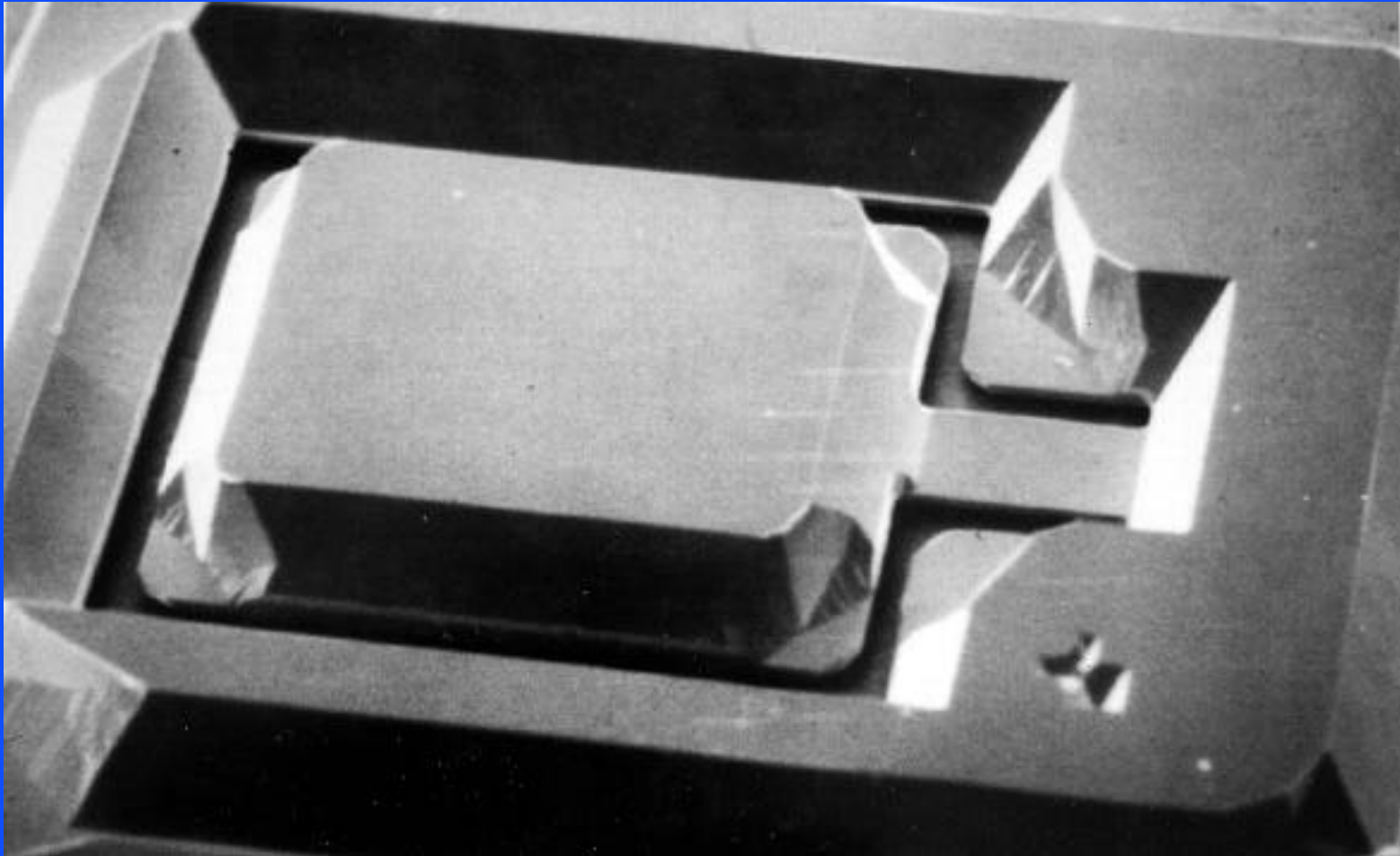
G. Kovacs © 2002

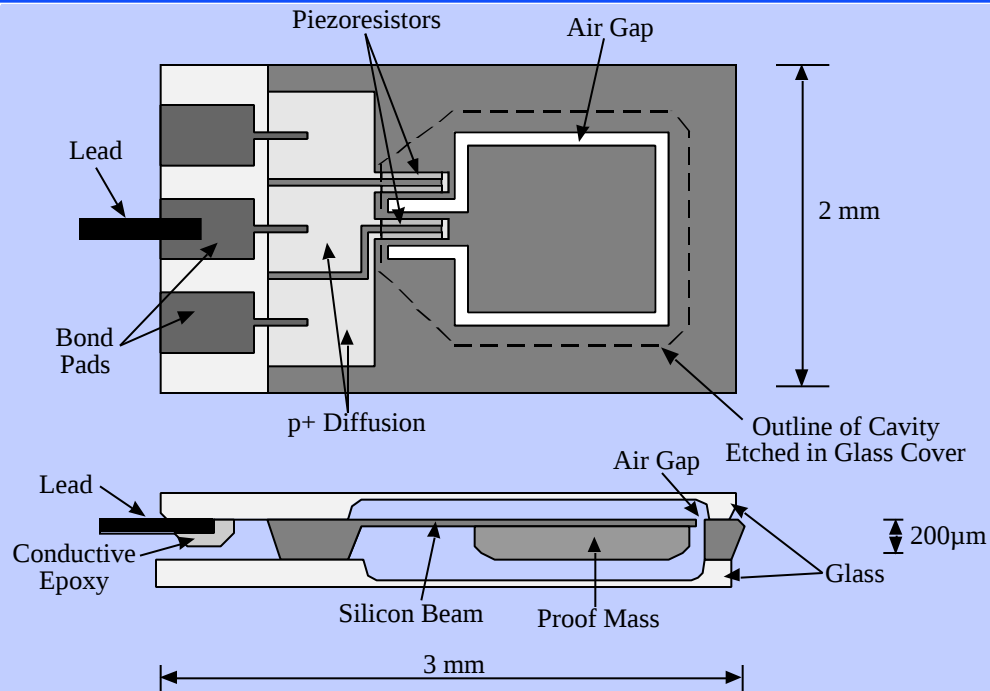


Courtesy Dr. S. Terry, EG&G IC Sensors, Inc.

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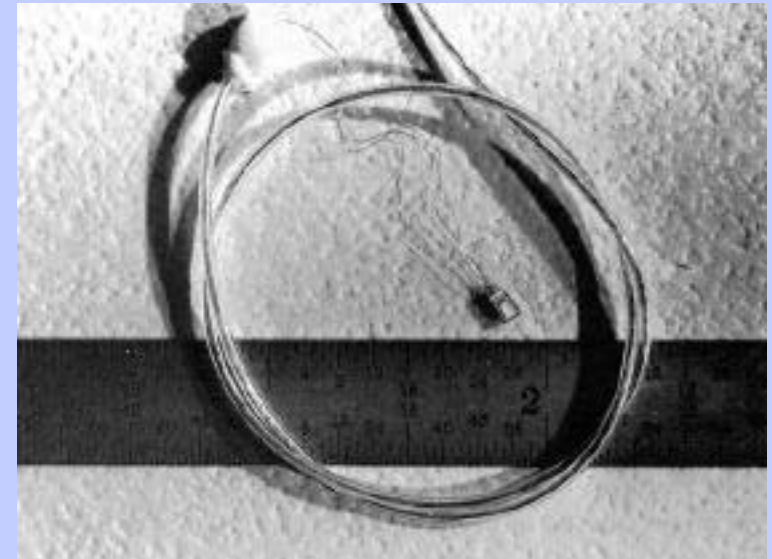
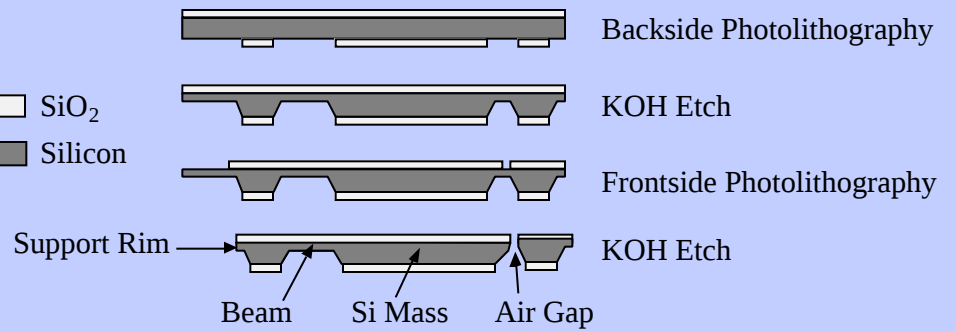
Roylance - Micromachined Accelerometer - 1974





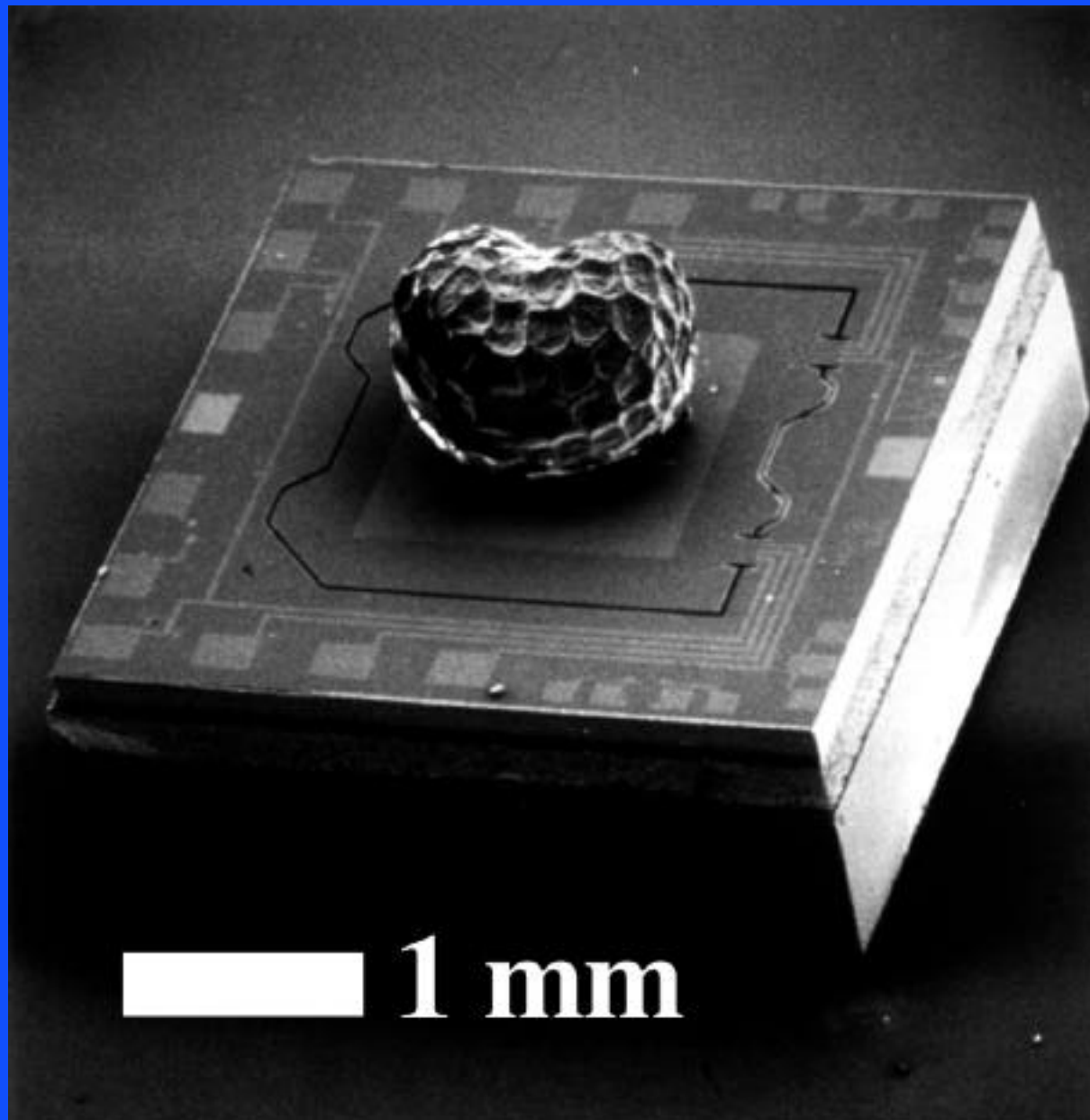
Reference: Roylance, L. M. and Angell, J. B., "A Batch-Fabricated Silicon Accelerometer," IEEE Transactions on Electron Devices, vol. ED-26, no. 12, Dec. 1979, pp. 1911 - 1917.

SiO₂
Silicon



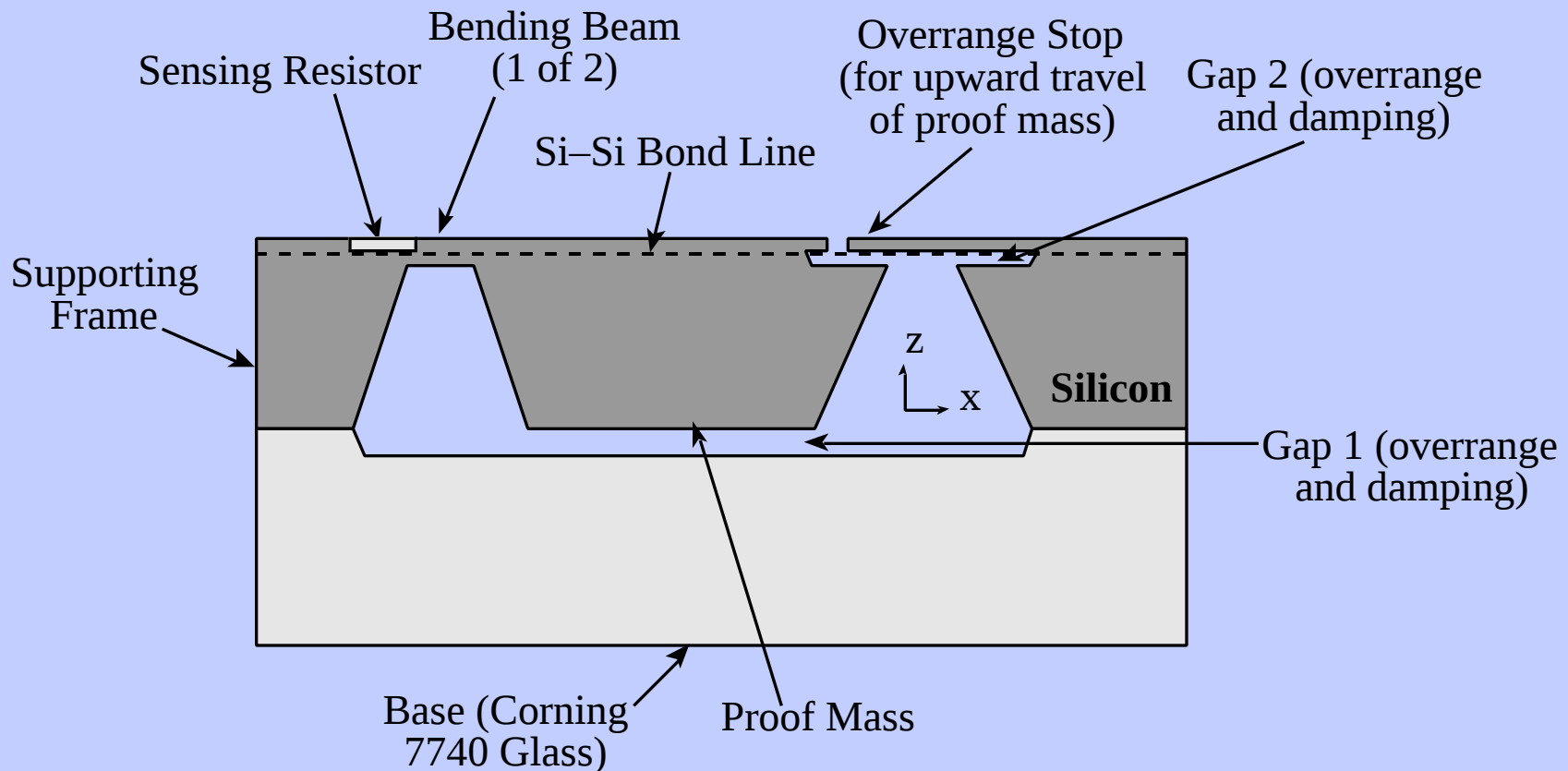
After Roylance and Angell (1979).

Modern Silicon Accelerometer

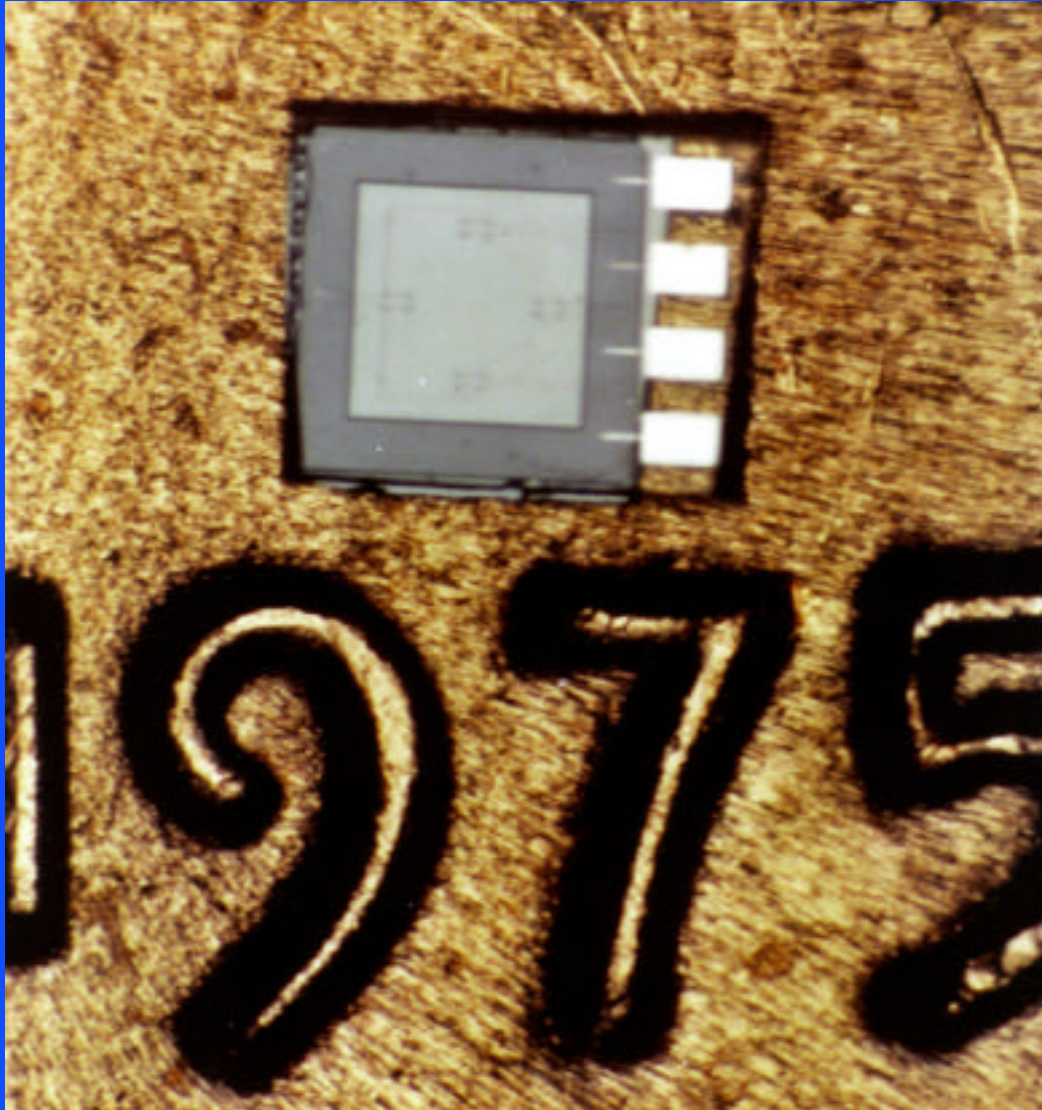


Courtesy of Dr. Kurt
Petersen, Lucas NovaSensor

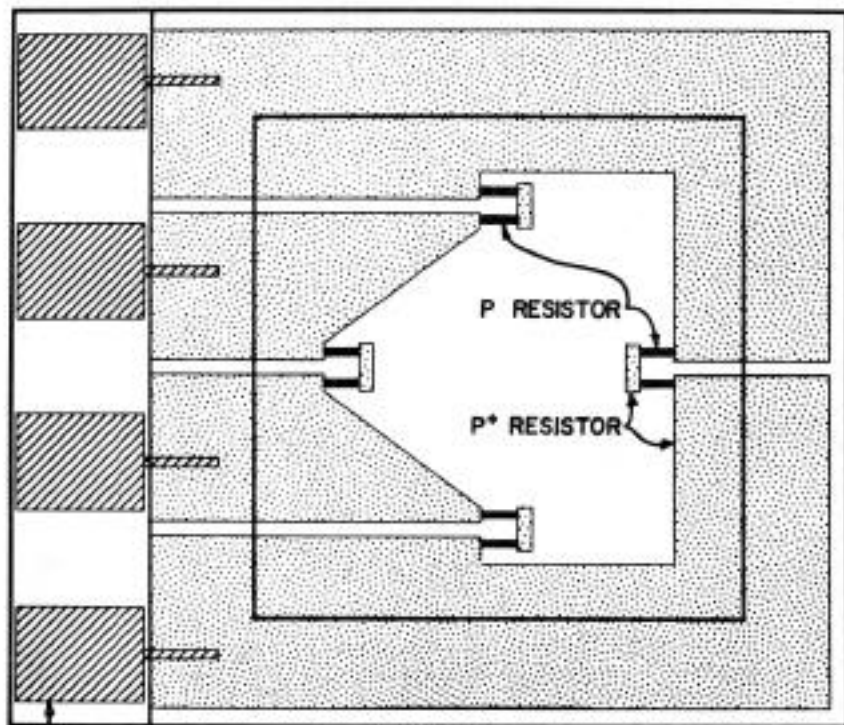
MODERN MICROMACHINED ACCELEROMETER (STRAIN GAUGE TYPE)



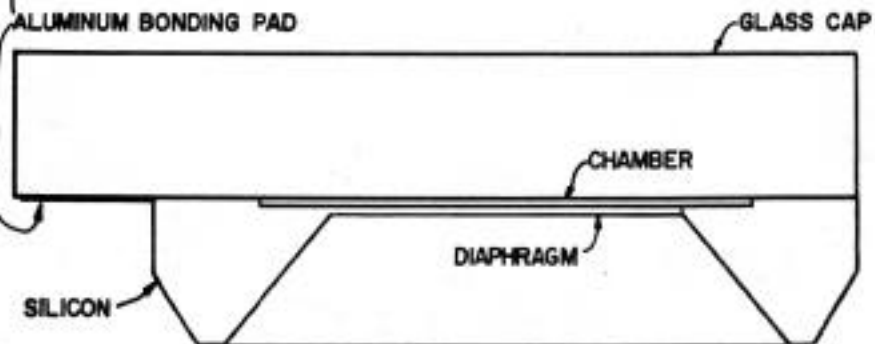
Barth - Absolute Pressure Sensor - 1974



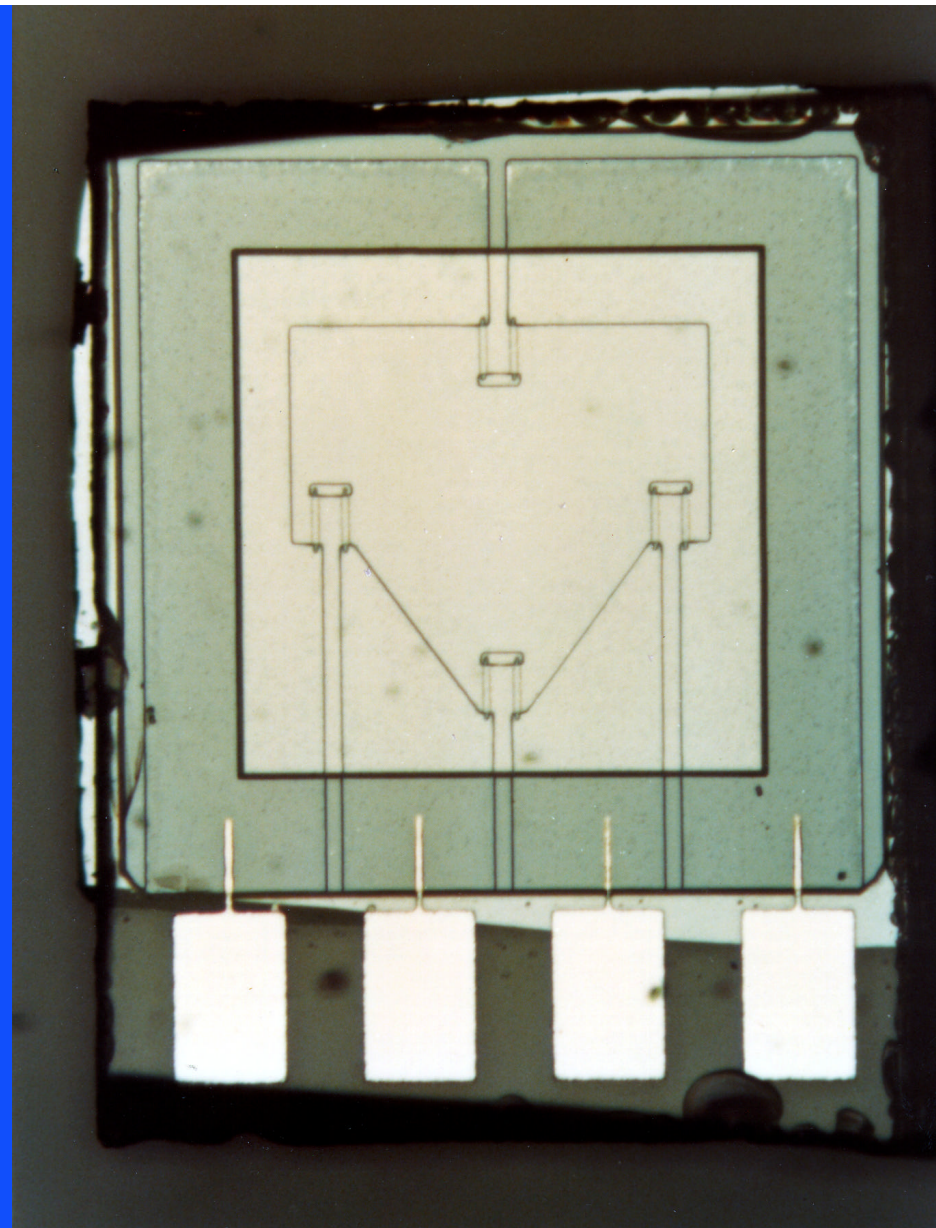
ABSOLUTE PRESSURE TRANSDUCER



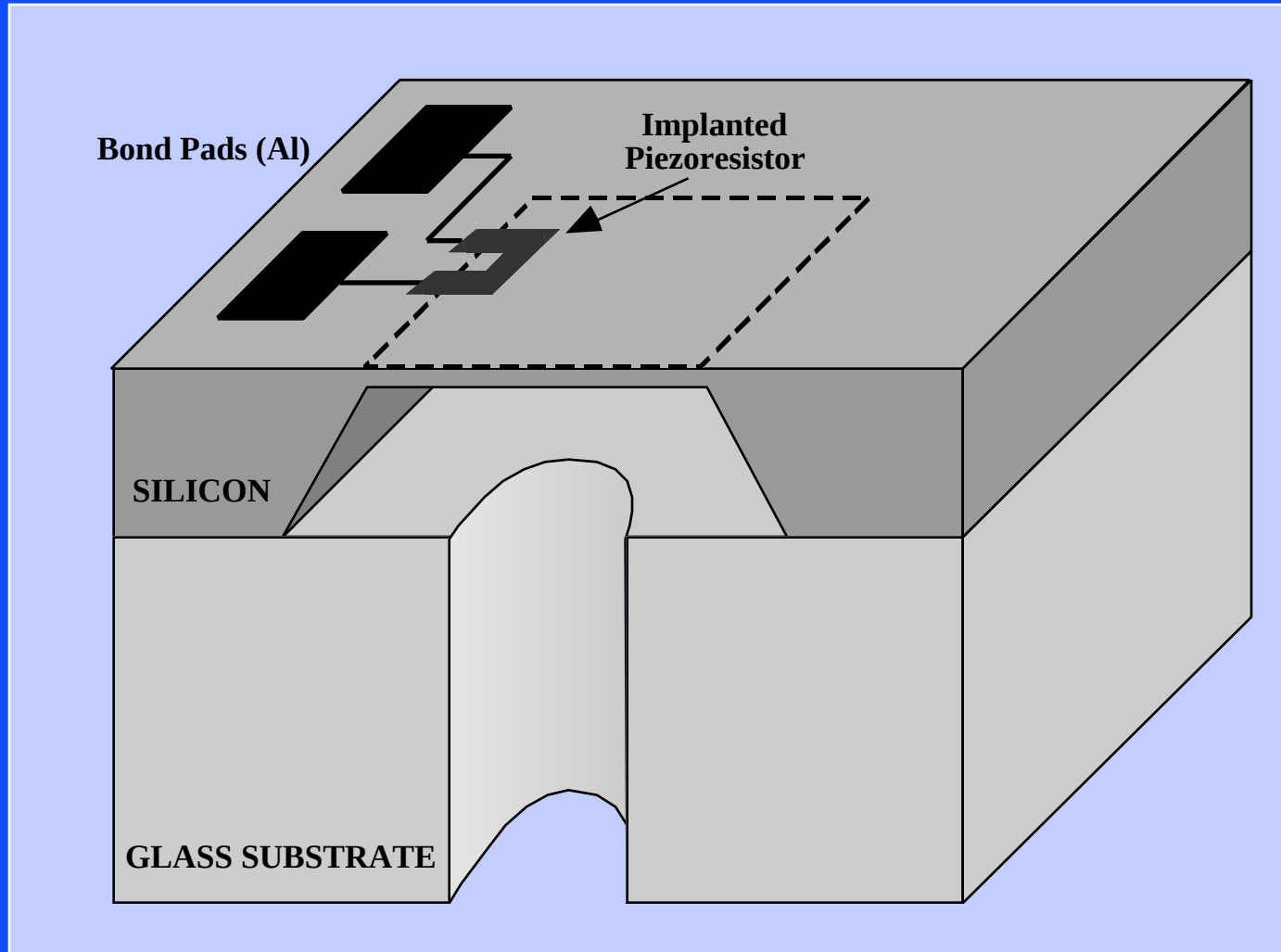
TOP VIEW
(LOOKING THRU GLASS CAP)



CROSS SECTION

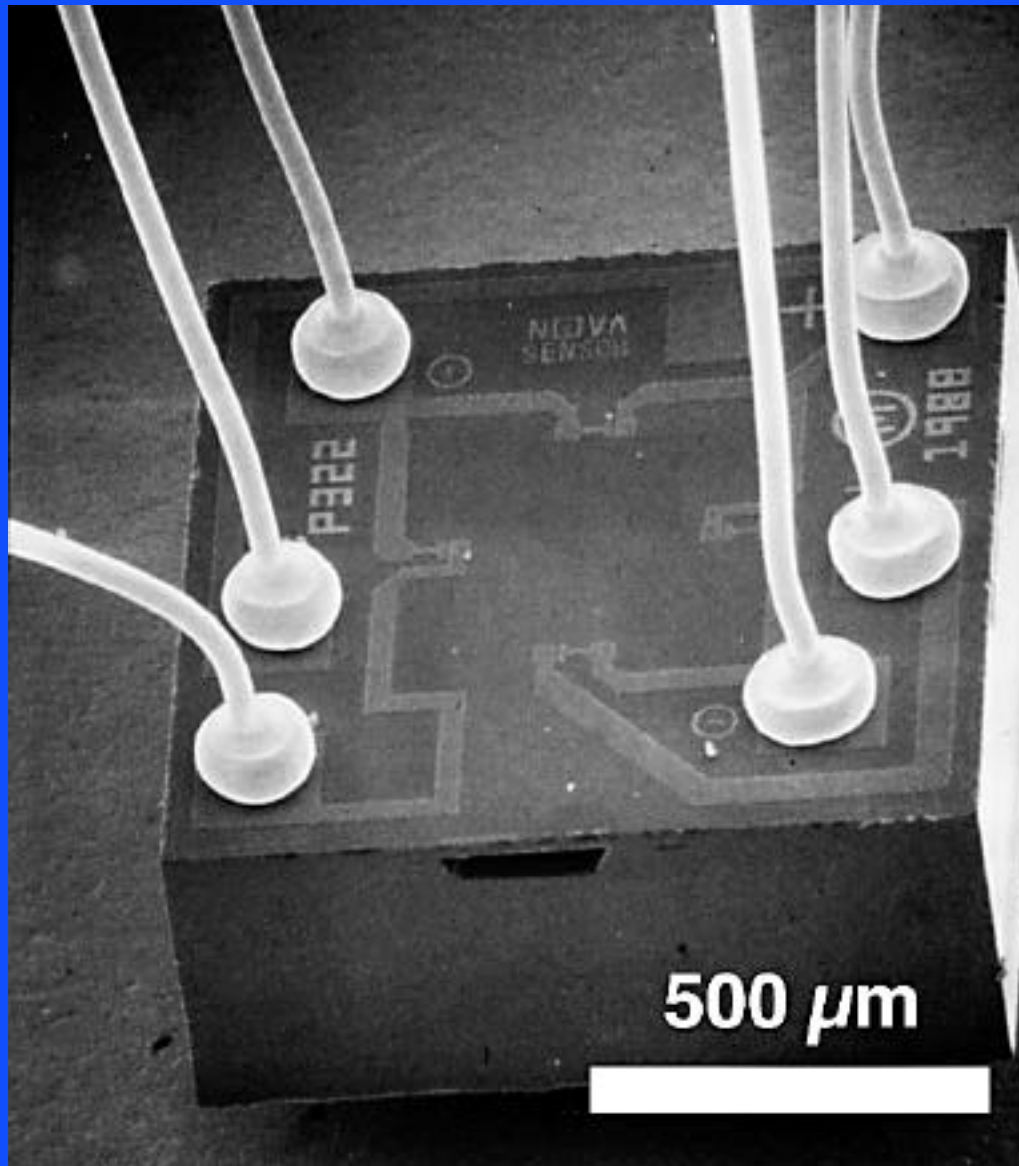


Modern Pressure Sensor

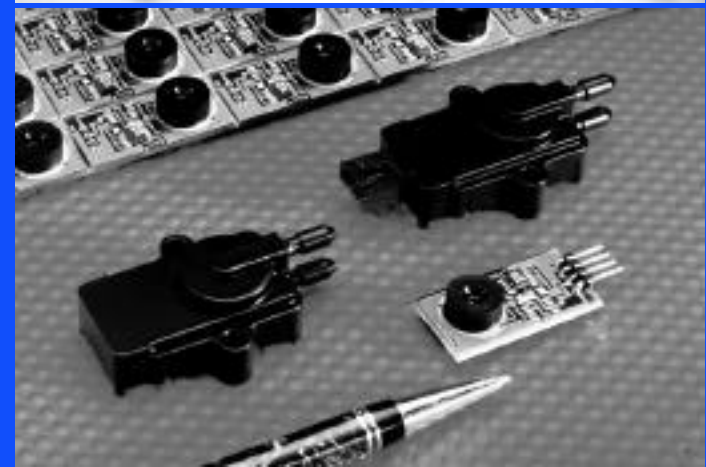


Reference: Bryzek, J., Petersen, K., Mallon, J. R., Christel, L., and Pourahmadi, F., "Silicon Sensors and Microstructures," Lucas NovaSensor, 1055 Mission Court, Fremont, CA, 1991.

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Images courtesy of Lucas NovaSensor.



Back Then, We Also Had a Space Station...

